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DISPLAY DEVICE

Abstract

A display device comprises a plurality of first banks disposed on a substrate to extend in a first direction and spaced apart from one another, a plurality of first patterns disposed between the plurality of first banks and spaced apart from one another in the first direction, a first electrode and a second electrode extending in the first direction and disposed on different first banks of the plurality of first banks and spaced apart from each other, a first insulating layer overlapping the plurality of first patterns, disposed on the first substrate, and to partially overlapping the first and second electrodes, and a plurality of light-emitting elements disposed on the first insulating layer so that first and second ends of each of the plurality of light-emitting elements are disposed on the first and second electrodes, respectively.

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Background/Summary

CROSS REFERENCE TO RELATED APPLICATION(S) [0001] This is a divisional application of U.S. patent application Ser. No. 17/162,315, filed Jan. 29, 2021 (now pending), the disclosure of which is incorporated herein by reference in its entirety. U.S. patent application Ser. No. 17/162,315 claims priority to and the benefit of Korean Patent Application No. 10-2020-0049997 under 35 U.S.C. § 119, filed in the Korean Intellectual Property Office (KIPO) on Apr. 24, 2020, the entire contents of which are incorporated herein by reference.

BACKGROUND

1. Technical Field

[0002] The disclosure relates to a display device.

2. Description of the Related Art

[0003] Display devices have become highly important with the development of multimedia, and various types of display devices, such as an organic light-emitting diode (OLED) display device, a liquid crystal display (LCD) device, or the like, have been used.

[0004] A display device, which is a device for displaying an image, includes a display panel such as an OLED display panel or an LCD panel. The display panel may include light-emitting elements such as light-emitting diodes (LEDs), and the LEDs may be classified into OLEDs that use an organic material as a fluorescent material and inorganic LEDs (ILEDs) that use an inorganic material as a fluorescent material.

SUMMARY

[0005] Embodiments of the disclosure provide a display device capable of minimizing the number of light-emitting elements that are lost during the fabrication thereof.

[0006] Embodiments of the disclosure provide a display device with an improved alignment of light-emitting elements on electrodes.

[0007] However, embodiments of the disclosure are not restricted to those set forth herein. The above and other embodiments of the disclosure will become more apparent to one of ordinary skill in the art to which the disclosure pertains by referencing the detailed description of the disclosure given below.

[0008] According to the aforementioned and other embodiments of the disclosure, a display device including a plurality of patterns, which are disposed between banks on which electrodes are arranged, is provided. The patterns are disposed to be spaced apart from one another in the direction in which the electrodes and the banks extend and can thus form height differences between the banks. The patterns, like the banks, can provide space in which light-emitting elements

are arranged, and the light-emitting elements can be guided to be placed between the patterns, which are separate from one another, during the fabrication of the display device.

[0009] Accordingly, the number of light-emitting elements that fail to be connected to the electrodes and are lost because of being disposed in regions other than that between the banks can be minimized. Also, since light-emitting elements disposed between the patterns can have both ends thereof properly placed on the electrodes, the alignment of the light-emitting elements can be improved.

[0010] Other features and embodiments may be apparent from the following detailed description, the drawings, and the claims.

[0011] According to an embodiment of the disclosure, a display device may comprise a plurality of first banks disposed on a substrate to extend in a first direction and spaced apart from one another; a plurality of first patterns disposed between the plurality of first banks and spaced apart from one another in the first direction; a first electrode and a second electrode extending in the first direction, disposed on different first banks of the plurality of first banks, and spaced apart from each other; a first insulating layer overlapping the plurality of first patterns, disposed on the substrate, and partially overlapping the first and second electrodes; and a plurality of light-emitting elements disposed on the first insulating layer so that first and second ends of each of the plurality of light-emitting elements are disposed on the first and second electrodes, respectively, the plurality of light-emitting elements including first light-emitting elements which are disposed between the plurality of first patterns not and do not overlap the plurality of first patterns in a thickness direction of the display device.

[0012] The plurality of light-emitting elements may further comprise second light-emitting elements which overlap the plurality of first patterns in the thickness direction of the display device, and distances between the first light-emitting elements and the substrate may be smaller than distances between the second light-emitting elements and the substrate.

[0013] A thickness of the plurality of first patterns may be greater than thicknesses of the first and second electrodes.

[0014] The thickness of the plurality of first patterns may be smaller than a diameter of the plurality of light-emitting elements.

[0015] The plurality of first patterns may be disposed between the first and second electrodes, and a width of the plurality of first patterns may be smaller than a distance between the first and second electrodes.

[0016] A width of the plurality of first patterns may be greater than a distance between the first and second electrodes, and at least portions of the first and second electrodes may be disposed on the plurality of first patterns.

[0017] The display device may further comprise a planarization layer disposed on the substrate. The plurality of first banks and the first insulating layer may be disposed on the planarization layer, and the plurality of first patterns and the planarization layer may be integral with each other.

[0018] The plurality of first patterns may overlap portions of the first or second electrode that do not overlap the plurality of first banks and be arranged in the first direction.

[0019] First patterns of the plurality of first patterns that overlap the first electrode and first patterns of the plurality of first patterns that overlap the second electrode may be arranged parallel to a direction in which the first and second electrodes are spaced apart from each other.

[0020] First patterns of the plurality of first patterns that overlap the first electrode and first patterns of the plurality of first patterns that overlap the second electrode may be arranged in a staggered manner.

[0021] The display device may further comprise a first contact electrode disposed on the first electrode to be in electrical contact with first ends of the plurality of light-emitting elements and a second contact electrode disposed on the second electrode to be in electrical contact with second ends of the plurality of light-emitting elements.

[0022] The first electrode may include at least one bent portion which extends in a second direction that is different from the first direction, an extended portion which has a greater width than the at least one bent portion, and at least one connecting portion which electrically connects the bent portions and the extended portion and extends in the first direction, and the plurality of first patterns may be disposed between the extended portion of the first electrode and the second electrode.

[0023] The second electrode may be symmetrical with the first electrode with respect to the first insulating layer, the plurality of first patterns may be disposed between the extended portion of the first electrode and an extended portion of the second electrode, and a first end and a second end of each of the plurality of light-emitting elements may be disposed on the extended portions of the first and second electrodes, respectively.

[0024] A first distance between the extended portion of the first electrode and the second electrode may be smaller than a second distance between the at least one connecting portion of the first electrode and the second electrode, and a minimum distance between the at least one bent portion of the first electrode and the second electrode may be greater than the first distance and is smaller than the second distance.

[0025] According to an embodiment of the disclosure, a display device may comprise a planarization layer disposed on the substrate; a plurality of first banks disposed on the planarization layer and spaced apart from one another; a first electrode and a second electrode disposed on different first banks of the plurality of first banks and spaced apart from each other; a first insulating layer disposed on the planarization layer and partially overlapping the first and second electrodes; first light-emitting elements disposed on the first insulating layer so that a first end and a second end of each of the first light-emitting elements are disposed on the first electrode and the second electrode, respectively; and second light-emitting elements disposed on the first insulating layer so that a first end and a second end of each of the second light-emitting elements are disposed on the first electrode and the second electrode, respectively, wherein a distance between the first light-emitting elements and the substrate is smaller than a distance between the second light-emitting elements and the substrate.

[0026] The planarization layer may include first patterns including top surfaces partially protruding between the plurality of first banks, and the second light-emitting elements may be disposed on the first patterns.

[0027] The planarization layer may include portions between the plurality of first banks where the first patterns are not formed, and the first light-emitting elements may be disposed on the portions of the planarization layer where the first patterns are not formed.

[0028] The planarization layer may include recesses between the plurality of first banks. A top surface of the planarization layer may be recessed, at least portions of the first and second electrodes may be disposed in the recesses, and the first light-emitting elements may be disposed in the recesses.

[0029] The planarization layer may include portions between the plurality of first banks where the recesses are not formed, and the second light-emitting elements may be disposed on the portions of the planarization layer where the recesses are not formed.

[0030] The display device may further comprise a transistor disposed between the substrate and the planarization layer; and a data conductive layer disposed between the transistor and the planarization layer and including a first voltage line and second voltage line, wherein the first electrode may be electrically connected to the first voltage line via the transistor, and the second electrode may be electrically connected to the second voltage line.

Description

BRIEF DESCRIPTION OF THE DRAWINGS

[0031] These and other aspects will become apparent and more readily appreciated from the following description of the embodiments, taken in conjunction with the accompanying drawings in which:

[0032] FIG. 1 is a schematic plan view of a display device according to an embodiment of the disclosure;

[0033] FIG. 2 is a schematic plan view of a pixel of the display device of FIG. 1;

[0034] FIG. 3 is a schematic cross-sectional view taken along lines Q1-Q1', Q2-Q2', and Q3-Q3' of FIG. 2;

[0035] FIG. 4 is a schematic cross-sectional view taken along line Q4-Q4' of FIG. 2;

[0036] FIG. 5 is a schematic cross-sectional view taken along line Q5-Q5' of FIG. 2;

[0037] FIG. 6 is a schematic enlarged cross-sectional view of portion QA of FIG. 4;

[0038] FIG. 7 is a schematic cross-sectional view taken along line Q6-Q6' of FIG. 2;

[0039] FIG. 8 is a schematic partial cross-sectional view of a display device according to another embodiment of the disclosure;

[0040] FIG. 9 is a schematic perspective view of a light-emitting element according to an embodiment of the disclosure;

[0041] FIGS. 10 through 12 are schematic cross-sectional views illustrating processes of a method of fabricating a display device according to an embodiment of the disclosure;

[0042] FIG. 13 is a schematic plan view of a subpixel obtained by the processes illustrated in FIG. 12;

[0043] FIGS. 14 and 15 are schematic cross-sectional views illustrating processes of the method of fabricating a display device according to an embodiment of the disclosure;

[0044] FIG. 16 is a schematic plan view of a subpixel obtained by the processes illustrated in FIGS. 14 and 15;

[0045] FIGS. 17 through 19 are schematic cross-sectional views illustrating the arrangement of light-emitting elements and first patterns in the subpixel of FIG. 16;

[0046] FIGS. 20 and 21 are schematic cross-sectional views illustrating processes of the method of fabricating a display device according to an embodiment of the disclosure;

[0047] FIGS. 22 through 24 are schematic partial cross-sectional views of display devices according to other embodiments of the disclosure;

[0048] FIGS. 25 and 26 are schematic partial cross-sectional views of display devices according to other embodiments of the disclosure;

[0049] FIG. 27 is a schematic partial cross-sectional view of a display device according to another embodiment of the disclosure;

[0050] FIG. 28 is a schematic plan view of a subpixel of the display device of FIG. 27;

[0051] FIG. 29 is a schematic plan view of a subpixel of a display device according to another embodiment of the disclosure;

[0052] FIG. 30 is a schematic cross-sectional view taken along line QB-QB' of FIG. 29;

[0053] FIG. 31 is a schematic plan view of a subpixel of a display device according to another embodiment of the disclosure;

[0054] FIG. 32 is a schematic cross-sectional view taken along lines QC-QC', QD-QD', and QE-QE' of FIG. 31;

[0055] FIG. 33 is a schematic plan view of a subpixel of a display device according to another embodiment of the disclosure;

[0056] FIG. 34 is a schematic plan view of a subpixel of a display device according to another embodiment of the disclosure; and

[0057] FIG. 35 is a schematic cross-sectional view taken along line QX-QX' of FIG. 34.

DETAILED DESCRIPTION OF THE EMBODIMENTS

[0058] The disclosure will now be described more fully hereinafter with reference to the accompanying drawings, in which preferred embodiments of the disclosure are shown. This disclosure may, however, be embodied in different forms and should not be construed as limited to the embodiments set forth herein. Rather, these embodiments are provided so that this disclosure will be thorough and complete, and will convey the scope of the disclosure to those skilled in the art.

[0059] It will also be understood that when a layer is referred to as being “on” another layer or substrate, it can be directly on the other layer or substrate, or one or more intervening layers may also be present. The same reference numerals indicate the same components throughout the specification.

[0060] It will be understood that although the terms “first,” “second,” or the like may be used herein to describe various elements, these elements should not be limited by these terms. These terms are only used to distinguish one element from another element. For instance, a first element discussed below could be termed a second element without departing from the teachings of the disclosure. Similarly, the second element could also be termed the first element.

[0061] Unless otherwise defined or implied herein, all terms (including technical and scientific terms) used have the same meaning as commonly understood by those skilled in the art to which this disclosure pertains. It will be further understood that terms, such as those defined in commonly used dictionaries, should be interpreted as having a meaning that is consistent with their meaning in the context of the relevant art and should not be interpreted in an ideal or excessively formal sense unless clearly defined in the specification.

[0062] Hereinafter, embodiments will be described with reference to the accompanying drawings.

[0063] FIG. 1 is a schematic plan view of a display device according to an embodiment of the disclosure.

[0064] The terms “above,” “top,” and “on,” as used herein, refer to an upward direction from a display device **10**, i.e., one direction of a third direction DR3, and the terms “below,” “bottom,” and “under,” as used herein, refer to a downward direction from the display device **10**, i.e., the other direction of the third direction DR3. The terms “left,” “right,” “upper,” and “lower,” as used herein, refer to their respective directions as viewed from above the display device **10**. For example, the terms “left,” “right,” “upper,” and “lower” refer to one direction of a first direction DR1, the other direction of the first direction DR1, one direction of a second direction DR2, and the other direction of the second direction DR2, respectively.

[0065] Referring to FIG. 1, a display device **10** displays a moving or still image. The display device **10** may refer to nearly all types of electronic devices that include a display screen. Examples of the display device **10** may include a television (TV), a notebook computer, a monitor, a billboard, an Internet-of-Things (IoT) device, a mobile phone, a smartphone, a tablet personal computer (PC), an electronic watch, a smartwatch, a watchphone, a head-mounted display, a mobile communication terminal, an electronic notepad, an electronic book, a portable multimedia player (PMP), a navigation device, a gaming console, a digital camera, and a camcorder.

[0066] The display device **10** may include a display panel that includes a display screen. Examples of the display panel include an inorganic light-emitting diode (ILED) display panel, an organic LED (OLED) display panel, a quantum-dot light-emitting diode (QLED) display panel, a plasma display panel (PDP), and a field emission display (FED) panel. The display panel of the display device **10** will hereinafter be described as being an ILED display panel, but the disclosure is not limited thereto.

[0067] The shape of the display device **10** may vary. For example, the display device **10** may have a rectangular shape that extends longer in a horizontal direction than in a vertical direction, a rectangular shape that extends longer in the vertical direction than in the horizontal direction, a square shape, a rectangular shape with rounded corners, another polygonal shape, or a circular shape. A display area DPA of the display device **10** may have a similar shape to the display device

10. FIG. 1 illustrates that the display device **10** and the display area DPA have a rectangular shape that extends longer in the horizontal direction than in the vertical direction.

[0068] The display device **10** may include the display area DPA and a non-display area NDA. The display area DPA is an area in which an image is displayed, and the non-display area NDA is an area in which an image is not displayed. The display area DPA may also be referred to as an active area, and the non-display area NDA may also be referred to as an inactive area. The display area DPA may generally account for a middle portion of the display device **10**.

[0069] The display area DPA may include pixels PX. The pixels PX may be arranged in row and column directions. The pixels PX may have a rectangular or square shape in a plan view, but the disclosure is not limited thereto. As another example, the pixels PX may have a rhombus shape that is inclined with respect to the first or second direction. As another example, the pixels PX may be arranged in a stripe fashion or a PenTile® fashion. Each of the pixels PX may include one or more light-emitting elements **30** that emit light of a predetermined wavelength range to emit light of a predetermined color.

[0070] The non-display area NDA may be disposed on the periphery of the display area DPA. The non-display area NDA may surround the entire display area DPA or a portion of the display area DPA. The display area DPA may have a rectangular shape, and the non-display area NDA may be disposed adjacent to four sides of the display area DPA. The non-display area NDA may form a bezel of the display device **10**. Wires or circuit drivers included in the display device **10** may be disposed in the non-display area NDA, or external devices may be mounted in the non-display area NDA.

[0071] FIG. 2 is a schematic plan view of a pixel of the display device of FIG. 1.

[0072] Referring to FIG. 2, a pixel PX may include subpixels PX_n (where n is an integer of 1 to 3). For example, the pixel PX may include first, second, and third subpixels PX1, PX2, and PX3. The first subpixel PX1 may emit light of a first color, the second subpixel PX2 may emit light of a second color, and the third subpixel PX3 may emit light of a third color. The first, second, and third colors may be blue, green, and red, respectively, but the disclosure is not limited thereto. As another example, the subpixels PX_n may emit light of the same color. FIG. 2 illustrates that the pixel PX includes three subpixels PX_n, but the disclosure is not limited thereto. As another example, the pixel PX may include more than three subpixels PX_n.

[0073] Each of the subpixels PX_n may include an emission area EMA and a non-emission area. The emission area EMA may be an area in which one or more light-emitting elements **30** are disposed to emit light of a particular wavelength range, and the non-emission area may be an area that light emitted from the light-emitting elements **30** does not extend to and no light is thus emitted from. The emission area EMA may include an area in which the light-emitting elements **30** are disposed, and an area that outputs light emitted from the light-emitting elements **30**.

[0074] However, the disclosure is not limited to this. The emission area EMA may further include an area in which light emitted from the light-emitting elements **30** is reflected or refracted by another element. Light-emitting elements **30** may be disposed in the subpixels PX_n and emission areas EMA, including areas where the light-emitting elements **30** are disposed and areas adjacent to the areas where the light-emitting elements **30** are disposed, may be formed.

[0075] Each of the subpixels PX_n may include a cut area CBA, which is disposed in the non-emission area. The cut area CBA may be disposed on one side, in the second direction DR2, of the emission area EMA. The cut area CBA may be disposed between emission areas EMA of a pair of adjacent subpixels PX_n in the second direction DR2. In the display area DPA of the display device **10**, emission areas EMA and cut areas CBA may be arranged. For example, the emission areas EMA or the cut areas CBA may be arranged one after another in the first direction DR1, and the emission areas EMA or the cut areas CBA may be alternately arranged in the second direction DR2. The distance, in the first direction DR1, between the cut areas CBA may be smaller than the distance, in the first direction DR1, between the emission areas EMA. A second bank **45** may be

disposed between the cut areas CBA and the emission areas EMA, and the distance between the cut areas CBA and the emission areas EMA may be determined by the width of the second bank **45**. No light-emitting elements **30** are disposed in the cut areas CBA so that no light is emitted from the cut areas CBA, but portions of electrodes **21** and **22** disposed in each of the subpixels PXn may be disposed in the corresponding cut area CBA to be separated from each other.

[0076] FIG. **3** is a schematic cross-sectional view taken along lines Q1-Q1', Q2-Q2', and Q3-Q3' of FIG. **2**. FIG. **4** is a schematic cross-sectional view taken along line Q4-Q4' of FIG. **2**. FIG. **5** is a schematic cross-sectional view taken along line Q5-Q5' of FIG. **2**. Specifically, FIG. **3** illustrates a schematic cross-sectional view of the first subpixel PX1 of FIG. **2**, but the structure of the first subpixel PX1 illustrated in FIG. **3** may be directly applicable to other pixels PX or other subpixels PXn. FIG. **3** illustrates a schematic cross-sectional view taken along the first direction DR1 of first light-emitting elements **30A** and second light-emitting elements **30B** of the first subpixel PX1. FIG. **4** illustrates a schematic cross-sectional view of first patterns **70** of the first subpixel PX1 with no light-emitting elements **30** disposed thereon, and FIG. **5** illustrates a schematic cross-sectional view of first patterns **70** of the first subpixel PX1 with light-emitting elements **30** disposed thereon.

[0077] Referring to FIGS. **3** through **5** and further to FIG. **2**, the display device **10** may include a first substrate **11** and a semiconductor layer, conductive layers, and insulating layers, which are disposed on the first substrate **11**.

[0078] The first substrate **11** may be an insulating substrate. The first substrate **11** may be formed of an insulating material such as glass, quartz, or a polymer resin. Also, the first substrate **11** may be a rigid substrate but may be a flexible substrate that is bendable, foldable, or rollable.

[0079] A light-blocking layer BML may be disposed on the first substrate **11**. The light-blocking layer BML is disposed to overlap an active layer ACT of a first transistor TR1. The light-blocking layer BML may include a material capable of blocking light and may prevent light from being incident upon the active layer ACT of the first transistor TR1. For example, the light-blocking layer BML may be formed of an opaque metal capable of blocking the transmission of light, but the disclosure is not limited thereto. In some embodiments, the light-blocking layer BML may not be provided.

[0080] A buffer layer **12** may be disposed on the entire surface of the first substrate **11** including the light-blocking layer BML. The buffer layer **12** may be formed on the first substrate **11** to protect the first transistor TR1, which is susceptible to moisture, from moisture that may penetrate the first substrate **11** and may perform a surface planarization function. The buffer layer **12** may include inorganic layers that are alternately stacked. For example, the buffer layer **12** may be formed as a multilayer film in which inorganic layers including at least one of silicon oxide (SiO.sub.x), silicon nitride (SiN.sub.x), and silicon oxynitride (SiON) are alternately stacked.

[0081] The semiconductor layer is disposed on the buffer layer **12**. The semiconductor layer may include the active layer ACT of the first transistor TR1. The semiconductor layer may be disposed to partially overlap a gate electrode GE in a first gate conductive layer.

[0082] FIG. **3** illustrates only the first transistor TR1 of the first subpixel PX1, but the number of transistors included in the first subpixel PX1 is not particularly limited. The first subpixel PX1 may include more than one transistor. For example, the first subpixel PX1 may include more than one transistor including the first transistor TR1, for example, two or three transistors.

[0083] The semiconductor layer may include polycrystalline silicon, monocrystalline silicon, or an oxide semiconductor. In a case where the semiconductor layer includes an oxide semiconductor, the active layer ACT may include conductor regions (ACT_a and ACT_b) and a channel region ACT_c between the conductor regions (ACT_a and ACT_b). The oxide semiconductor may be an oxide semiconductor including indium (In). In some embodiments, the oxide semiconductor may be indium tin oxide (ITO), indium zinc oxide (IZO), indium gallium oxide (IGO), indium zinc tin oxide (IZTO), indium gallium tin oxide (IGTO), indium gallium zinc oxide (IGZO), or indium gallium zinc tin oxide (IGZTO), but the disclosure is not limited thereto.

[0084] As another example, the semiconductor layer may include polycrystalline, which is formed by crystallizing amorphous silicon. In this case, the conductor regions (ACT_a and ACT_b) of the active layer ACT may be regions doped with impurities.

[0085] A first gate insulating layer **13** is disposed on the semiconductor layer and the buffer layer **12**. The first gate insulating layer **13** may include a semiconductor layer and may be disposed on the buffer layer **12**. The first gate insulating layer **13** may function as the gate insulating film of each of transistors. The first gate insulating layer **13** may be formed as an inorganic layer including an inorganic material such as, for example, SiO.sub.x, SiN.sub.x, or SiON or as a stack of SiO.sub.x, SiN.sub.x, and/or SiON.

[0086] The first gate conductive layer is disposed on the first gate insulating layer **13**. The first gate conductive layer may include the gate electrode GE of the first transistor TR1 and a first capacitor electrode CSE of a storage capacitor. The gate electrode GE may be disposed to overlap the channel region ACT_c of the active layer ACT in a thickness direction. The first capacitor electrode CSE may be disposed to overlap a first source/drain electrode SD1 of the first transistor TR1 in the thickness direction. In some embodiments, the first capacitor electrode CSE may be connected to, and be integrated into a single layer with, the gate electrode GE, and the single layer may include, in part, the gate electrode GE and the first capacitor electrode CSE. The first capacitor electrode CSE may be disposed to overlap the first source/drain electrode SD1 in the thickness direction so that the storage capacitor may be formed between the first capacitor electrode CSE and the first source/drain electrode SD1.

[0087] The first gate conductive layer may be formed as a single-or multilayer film including molybdenum (Mo), aluminum (Al), chromium (Cr), gold (Au), titanium (Ti), nickel (Ni), neodymium (Nd), copper (Cu), or an alloy thereof, but the disclosure is not limited thereto.

[0088] A first passivation layer **15** is disposed on the first gate conductive layer. The first passivation layer **15** may cover or overlap the first gate conductive layer to protect the first gate conductive layer. The first passivation layer **15** may be formed as an inorganic layer including an inorganic material such as, for example, SiO.sub.x, SiN.sub.x, or SiON or as a stack of SiO.sub.x, SiN.sub.x, and/or SiON.

[0089] A first data conductive layer is disposed on the first passivation layer **15**. The first data conductive layer may include the first source/drain electrode SD1, a second source/drain electrode SD2, and a data line DTL.

[0090] Source/drain electrodes (SD1 and SD2) of the first transistor TR1 may be in electrical contact with the conductor regions (ACT_a and ACT_b) of the active layer ACT via contact holes that penetrate the first interlayer insulating layer **17** and the first gate insulating layer **13**. The second source/drain electrode SD2 of the first transistor TR1 may be electrically connected to the light-blocking layer BML via another contact hole.

[0091] The data line DTL may apply a data signal to other transistors (not illustrated) of the first subpixel PX1. Although not specifically illustrated, the data line DTL may be electrically connected to the source/drain electrodes of the other transistors and may transmit the data signal to the source/drain electrodes of the other transistors.

[0092] The first data conductive layer may be formed as a single-or multi-layer film including Mo, Al, Cr, Au, Ti, Ni, Nd, Cu, or an alloy thereof, but the disclosure is not limited thereto.

[0093] The first interlayer insulating layer **17** is disposed on the first data conductive layer. The first interlayer insulating layer **17** may function as an insulating film between the first data conductive layer and layers disposed on the first data conductive layer. Also, the first interlayer insulating layer **17** may cover or overlap the first data conductive layer to protect the first data conductive layer. The first interlayer insulating layer **17** may be formed as an inorganic layer including an inorganic material such as, for example, SiO.sub.x, SiN.sub.x, or SiON or as a stack of SiO.sub.x, SiN.sub.x, and/or SiON.

[0094] A second data conductive layer is disposed on the first interlayer insulating layer **17**. The

second data conductive layer may include a first voltage line VL1, a second voltage line VL2, and a first conductive pattern CDP. A high-potential voltage (or the first power supply voltage) provided to the first transistor TR1 may be applied to the first voltage line VL1, and a low-potential voltage (or the second power supply voltage) provided to a second electrode 22 may be applied to the second voltage line VL2. A light-emitting element alignment signal for aligning light-emitting elements 30 may also be applied to the second voltage line VL2 during the fabrication of the display device 10.

[0095] The first conductive pattern CDP may be electrically connected to the second source/drain electrode SD2 of the first transistor TR1 via a contact hole formed in the first interlayer insulating layer 17. The first conductive pattern CDP may be in electrical contact with a first electrode 21 that will be described below. The first transistor TR1 may transmit the first power supply voltage, applied from the first voltage line VL1, to the first electrode 21 via the first conductive pattern CDP. The second data conductive layer is illustrated as including one first voltage line VL1 and one second voltage line VL2, but the disclosure is not limited thereto. As another example, the second data conductive layer may include more than one first voltage line VL1 and more than one second voltage line VL2.

[0096] The second data conductive layer may be formed as a single-or multi-layer film including Mo, Al, Cr, Au, Ti, Ni, Nd, Cu, or an alloy thereof, but the disclosure is not limited thereto.

[0097] A first planarization layer 19 is disposed on the second data conductive layer. The first planarization layer 19 may include an organic insulating material such as, for example, polyimide (PI), and may perform a surface planarization function.

[0098] First banks 40, first patterns 70, electrodes (21 and 22), light-emitting elements 30, a second bank 45, and contact electrodes (26 and 27) may be disposed on the first planarization layer 19. Insulating layers (51, 52, 53, and 54) may be further disposed on the first planarization layer 19.

[0099] The first banks 40 may be disposed directly on the first planarization layer 19. The first banks 40 may extend in the second direction DR2 within the first subpixel PX1; may not extend into neighboring subpixels PXn, in the second direction DR2, of the first subpixel PX1; and may be disposed in an emission area EMA of the first subpixel PX1. The first banks 40 may be disposed to be spaced apart from one another in the first direction DR1 and may form a region where the light-emitting elements 30 are to be disposed. The first banks 40 may be disposed in each subpixel PXn to form linear patterns in the display area DPA of the display device 10. Two first banks 40 are illustrated as being provided in the first subpixel PX1, but the disclosure is not limited thereto. More than two first banks 40 may be disposed in the first subpixel depending on the number of electrodes (21 and 22) that will be described below.

[0100] The first banks 40 may protrude, at least in part, from the top surface of the first planarization layer 19. Portions of the first banks 40 that protrude may have inclined side surfaces, and light emitted from the light-emitting elements 30 may travel toward the inclined side surfaces. The electrodes (21 and 22), which are disposed on the first banks 40, may include a material with high reflectance, and light emitted from the light-emitting elements 30 may be reflected to be emitted in an upward direction from the first planarization layer 19. For example, the first banks 40 may not only provide an area in which to arrange the light-emitting elements 30, but also may function as a reflecting barrier capable of reflecting light emitted from the light-emitting elements 30 in the upward direction from the first planarization layer 19. The sides of the first banks 40 may be linearly inclined, but the disclosure is not limited thereto. As another example, the first banks 40 may have a semi-circular or elliptical shape with a curved outer surface. The first banks 40 may include an organic insulating material such as PI, but the disclosure is not limited thereto.

[0101] The display device 10 may include first patterns 70, which are disposed between the first banks 40. The first patterns 70 may have a smaller width than the first banks 40 and may be disposed to be spaced apart from one another in the second direction DR2, between the first banks 40. The width of the first patterns 70 may be smaller than the distance between the first banks 40,

and the first patterns **70** may be spaced apart from the first banks **40**. In some embodiments, the first patterns **70** and the first banks **40** may include the same material and may be formed at the same time.

[0102] As already mentioned above, the first banks **40** may form the region where the light-emitting elements **30** are to be disposed. During the fabrication of the display device **10**, ink having the light-emitting elements **30** scattered therein may be sprayed on the electrodes (**21** and **22**), and the light-emitting elements **30** may be arranged on the electrodes (**21** and **22**) by an electric field generated on the electrodes (**21** and **22**). Here, the first banks **40** may protrude from the top surface of the first planarization layer **19** to define a region therebetween and a region on the outside thereof and may guide the light-emitting elements **30** to be placed between the first banks **40**. Similarly, the first patterns **70**, which are disposed between the first banks **40**, may generate height differences in the region between the first banks **40** where the light-emitting elements **30** are disposed. Thus, regions where the first patterns **70** are disposed may be differentiated from regions between the first patterns **70** spaced apart from one another in the second direction DR2, and the light-emitting elements **30** may be guided to be placed between the first patterns **70**. As a result, the light-emitting elements **30** can be densely arranged in a particular area between the first banks **40**, and both ends of each of the light-emitting elements **30** can be properly arranged on the electrodes (**21** and **22**). The first patterns **70** will be described below in detail.

[0103] Electrodes (**21** and **22**) are disposed on the first bank **40** and the first planarization layer **19**. The electrodes (**21** and **22**) may include the first and second electrodes **21** and **22**. The first and second electrodes **21** and **22** may extend in the second direction DR2 and may be spaced apart from each other in the first direction DR1.

[0104] The first and second electrodes **21** and **22** may extend in the second direction DR2 in each subpixel PXn and may be separated from other electrodes (**21** and **22**) by the cut area CBA of the corresponding subpixel PXn. In some embodiments, a cut area CBA may be disposed between the emission areas EMA of two adjacent subpixels PXn in the second direction DR2, and first and second electrodes **21** and **22** of one of the two adjacent subpixels PXn may be separated from first and second electrodes **21** and **22** of the other subpixel PXn, but the disclosure is not limited thereto. As another example, some electrodes (**21** and **22**) may not be segmented between subpixels PXn, but may extend across the boundary between each pair of adjacent subpixels PXn in the second direction DR2, or only one of the first and second electrodes **21** and **22** may be segmented between the subpixels PXn.

[0105] The first electrode **21** may be electrically connected to the first transistor TR1 via a first contact hole CT1, and the second electrode **22** may be electrically connected to the second voltage line VL2 via a second contact hole CT2. For example, the first electrode **21** may be in electrical contact with the first conductive pattern CDP via the first contact hole CT1, which penetrates the first planarization layer **19** in an area where the second bank **45** extends in the first direction DR1, and the second electrode **22** may be in electrical contact with the second voltage line VL2 via a second contact hole CT2, which penetrates the first planarization layer **19** in the area where the second bank **45** extends in the first direction DR1. However, the disclosure is not limited to this example. In another example, the first and second contact holes CT1 and CT2 may be disposed in the emission area EMA surrounded by the second bank **45** not to overlap the second bank **45**.

[0106] One first electrode **21** and one second electrode **22** are illustrated as being provided in each subpixel PXn, but the disclosure is not limited thereto. More than one first electrode **21** and more than one second electrode **22** may be provided in each subpixel PXn. Also, in each subpixel PXn, the first and second electrodes **21** and **22** may not necessarily extend in one direction but may be arranged in various other fashions. For example, the first and second electrodes **21** and **22** may be partially curved or bent, or one of the first and second electrodes **21** and **22** may be disposed to surround the other electrode.

[0107] The first and second electrodes **21** and **22** may be disposed on their respective first banks

40. In some embodiments, the first and second electrodes **21** and **22** may be formed to have a greater width than the first banks **40**. For example, the first and second electrodes **21** and **22** may be formed to cover the outer surfaces of their respective first banks **40**. The first and second electrodes **22** may be disposed on the sides of their respective first banks **40**, and the distance between the first and second electrodes **21** and **22** may be smaller than the distance between the first banks **40**. The first and second electrodes **21** and **22** may be disposed, at least in part, directly on the first planarization layer **19** and may thus be on the same plane.

[0108] The electrodes (**21** and **22**) may include a conductive material with high reflectance. For example, the electrodes (**21** and **22**) may include a metal with high reflectance such as Ag, Cu, or Al or may include an alloy of Al, Ni, or La. The electrodes (**21** and **22**) may reflect light emitted from the light-emitting elements **30** to travel toward the sides of the first banks **40** in an upward direction from each subpixel PXn.

[0109] However, the disclosure is not limited to this, and the electrodes (**21** and **22**) may further include a transparent conductive material. For example, the electrodes (**21** and **22**) may include a material such as ITO, IZO, or ITZO. In some embodiments, each of the electrodes (**21** and **22**) may form a structure in which a transparent conductive material and a metal with high reflectance are stacked into more than one layer, or may be formed as a single layer including a transparent conductive material and a metal with high reflectance. For example, each of the electrodes (**21** and **22**) may have a stack of ITO/Ag/ITO, ITO, ITO/Ag/IZO, or ITO/Ag/ITZO/IZO.

[0110] The electrodes (**21** and **22**) may be electrically connected to the light-emitting elements **30**, and a predetermined voltage may be applied to each of the electrodes (**21** and **22**) so that the light-emitting elements **30** can emit light. For example, the electrodes (**21** and **22**) may be electrically connected to the light-emitting elements **30** via the contact electrodes (**26** and **27**) that will be described below, and may transmit electrical signals applied thereto to the light-emitting elements **30** via the contact electrodes (**26** and **27**).

[0111] One of the first and second electrodes **21** and **22** may be electrically connected to anode electrodes of the light-emitting elements **30**, and the other electrode of the first and second electrodes **21** and **22** may be electrically connected to cathode electrodes of the light-emitting elements **30**. However, the disclosure is not limited to this. As another example, one of the first and second electrodes **21** and **22** may be electrically connected to the cathode electrodes of the light-emitting elements **30**, and the other electrode of the first and second electrodes **21** and **22** may be electrically connected to the anode electrodes of the light-emitting elements **30**.

[0112] The electrodes (**21** and **22**) may be used to generate an electric field in each subpixel PXn to align the light-emitting elements **30**. The light-emitting elements **30** may be arranged between the first and second electrodes **21** and **22** by the electric field formed on the first and second electrodes **21** and **22**. The light-emitting elements **30** may be sprayed on the electrodes (**21** and **22**) via inkjet printing. If ink including the light-emitting elements **30** is sprayed on the electrodes (**21** and **22**), alignment signals may be applied to the electrodes (**21** and **22**) to generate an electric field. The light-emitting elements **30** scattered in the ink may receive a dielectrophoretic force from the electric field generated on the electrodes (**21** and **22**) and may thus be properly aligned on the electrodes (**21** and **22**).

[0113] A first insulating layer **51** is disposed on the first planarization layer **19**. The first insulating layer **51** may be disposed to cover the first banks **40**, the first and second electrodes **21** and **22**, and the first patterns **70**, over the first planarization layer **19**, but to expose portions of the top surfaces of the first and second electrodes **21** and **22**. In other words, the first insulating layer **51** may be formed substantially on the entire surface of the first planarization layer **19** and may include openings (not illustrated) that expose portions of the first and second electrodes **21** and **22**.

[0114] For example, portions of the top surface of the first insulating layer **51** may be recessed between the first and second electrodes **21** and **22** to generate height differences. As the first insulating layer **51** is disposed to cover or overlap the first patterns **70** between the first banks **40**,

height differences may be generated in portions of the top surface of the first insulating layer **51** along the direction in which the first patterns **70** are arranged, i.e., along the second direction DR2. As the first insulating layer **51** is disposed to cover the first and second electrodes **21** and **22**, even in the regions where the first patterns **70** are not disposed, height differences may be generated even in portions of the top surface of the first insulating layer **51** between the first and second electrodes **21** and **22**. However, the disclosure is not limited to this.

[0115] The first insulating layer **51** may protect the first and second electrodes **21** and **22** and may insulate the first and second electrodes **21** and **22** from each other. Also, the first insulating layer **51** may prevent the light-emitting elements **30**, which are disposed on the first insulating layer **51**, from being in direct contact with, and damaged by, other elements.

[0116] The second bank **45** may be disposed on the first insulating layer **51**. In a plan view, the second bank **45** may include portions that extend in the first direction DR1 and portions that extend in the second direction DR2 and may be arranged in a lattice pattern on the entire surface of the display area DPA. The second bank **45** may be disposed along the boundaries of each subpixel PXn to define each subpixel PXn.

[0117] The second bank **45** may be disposed to surround the emission area EMA and the cut area CBA of each subpixel PXn to separate the emission area EMA and the cut area CBA of each subpixel PXn. The first and second electrodes **21** and **22** may extend in the second direction DR2 across the portions of the second bank **45** that extend in the first direction DR1. The portions of the second bank **45** that extend in the second direction DR2 may have a greater width between emission areas EMA of each pair of adjacent subpixels PXn than between cut areas CBA of each pair of adjacent subpixels PXn. Accordingly, the distance between the cut areas CBA may be smaller than the distance between the emission areas EMA.

[0118] The second bank **45** may be formed to have a greater height than the first banks **40**. The second bank **45** may prevent ink from spilling over between different subpixels PXn during an inkjet printing process during the fabrication of the display device **10**. The second bank **45** may separate ink having the light-emitting elements **30** scattered therein between different subpixels PXn and may prevent mixture of the ink. The second bank **45**, like the first banks **40**, may include polyimide (PI), but the disclosure is not limited thereto.

[0119] The light-emitting elements **30** may be disposed on the first insulating layer **51**. Light-emitting elements **30** may be disposed to be spaced apart from one another in the direction in which the electrodes (**21** and **22**) extend, i.e., in the second direction DR2, and may be aligned substantially in parallel to one another. The distance between the light-emitting elements **30** is not particularly limited. The light-emitting elements **30** may extend in one direction, and the direction in which the electrodes (**21** and **22**) extend may form a substantially right angle with the direction in which the light-emitting elements **30** extend. However, the disclosure is not limited to this. As another example, the light-emitting elements **30** may be arranged diagonally with respect to the direction in which the electrodes (**21** and **22**) extend.

[0120] The light-emitting elements **30** may include light-emitting layers **36** having different materials and may emit light of different wavelength ranges to the outside. The display device **10** may include light-emitting elements **30** that emit light of different wavelength ranges. Accordingly, the first, second, and third subpixels PX1, PX2, and PX3 can emit light of the first, second, and third colors, respectively, but the disclosure is not limited thereto. As another example, the subpixels PXn may include light-emitting elements **30** of the same type and may emit light of substantially the same color.

[0121] The light-emitting element **30** may be arranged between the first banks **40** so that both ends thereof may be placed on the electrodes (**21** and **22**). For example, first ends of the light-emitting elements **30** may be disposed on the first electrode **21**, and second ends of the light-emitting elements **30** may be disposed on the second electrode **22**. The length of the light-emitting elements **30** may be greater than the distance between the first and second electrodes **21** and **22**, and both

ends of each of the light-emitting elements **30** may be disposed on the first and second electrodes **22**.

[0122] The light-emitting elements **30** may be disposed between the first patterns **70** or on the first patterns **70**. For example, the light-emitting elements **30** may include first light-emitting elements **30A**, which are disposed in the regions where the first patterns **70** are not disposed, and second light-emitting elements **30B**, which are disposed on the first patterns **70**. The first insulating layer **51** may be disposed between the first banks **40** and between the first and second electrodes **21** and **22** to cover the first patterns **70**. The light-emitting elements **30**, which are disposed on the first insulating layer **51**, may be disposed on portions of the first insulating layer **51** that are relatively low between the first patterns **70**, and at least some of the light-emitting elements **30** may be disposed to overlap the first patterns **70** in the thickness direction. FIG. **3** illustrates a schematic cross-sectional view taken from one end to the other end of one of the first light-emitting elements **30A**, and FIG. **4** illustrates a schematic cross-sectional view taken from one end to the other end of one of the second light-emitting elements **30B**. For example, the first patterns **70** may be disposed between the first banks **40** to generate height differences in the first insulating layer **51**, and the light-emitting elements **30** may include first light-emitting elements **30A** that are located relatively low and second light-emitting elements **30B** that are located relatively high. As the first patterns **70** are provided, most of the light-emitting elements **30** may be the first light-emitting elements **30A**, which are located relatively low. The first light-emitting elements **30A** may be light-emitting elements **30** that are guided by the height differences generated by the first patterns **70** to have their both ends placed on the electrodes (**21** and **22**). Some of the light-emitting elements **30**, e.g., the second light-emitting elements **30B**, may be located relatively high, e.g., on the first patterns **70**, and may be electrically connected to the first and second electrodes **21** and **22**.

[0123] However, the disclosure is not limited to this. As another example, the light-emitting elements **30** may not be arranged on the first patterns **70** depending on the arrangement and the shape of the first patterns **70**, and this will be described below.

[0124] In each of the light-emitting elements **30**, layers may be disposed in a direction perpendicular to the top surface of the first substrate **11** or the first planarization layer **19**. The light-emitting elements **30** may be arranged so that the direction in which the light-emitting elements **30** extend may be parallel to the first planarization layer **19**, and the semiconductor layers included in each of the light-emitting elements **30** may be sequentially disposed in a direction parallel to the top surface of the first planarization layer **19**. However, the disclosure is not limited to this. As another example, the semiconductor layers included in each of the light-emitting elements **30** may be disposed in the direction perpendicular to the first planarization layer **19**.

[0125] Both ends of each of the light-emitting elements **30** may be in electrical contact with the contact electrodes (**26** and **27**). For example, an insulating film **38** may not be formed on the ends of each of the light-emitting elements **30** so that some of the semiconductor layers included in each of the light-emitting elements **30** may be exposed and may thus be in electrical contact with the contact electrodes (**26** and **27**), but the disclosure is not limited thereto. As another example, the insulating film **38** may be removed from at least portions of the light-emitting elements **30** so that sides of the semiconductor layers of each of the light-emitting elements **30** may be partially exposed at both ends of each of the light-emitting elements **30** and may thus be in direct contact with the contact electrodes (**26** and **27**).

[0126] A second insulating layer **52** may be disposed on portions of the light-emitting elements **30**. For example, the second insulating layer **52** may be disposed to surround portions of the outer surfaces of the light-emitting elements **30**, but not to cover both ends of each of the light-emitting elements **30**. The contact electrodes (**26** and **27**) may be in electrical contact with both ends of each of the light-emitting elements **30**, not covered by the second insulating layer **52**. In a plan view, portions of the second insulating layer **52** on the light-emitting elements **30** may be disposed to extend in the second direction DR2 on the first insulating layer **51** and thus to form linear or island

patterns in the first subpixel PX1. The second insulating layer 52 may protect and fix the light-emitting elements 30 during the fabrication of the display device 10.

[0127] Contact electrodes (26 and 27) and a third insulating layer 53 may be disposed on the second insulating layer 52.

[0128] The contact electrodes (26 and 27) may extend in one direction. First and second contact electrodes 26 and 27 may be disposed on portions of the first and second electrodes 21 and 22, respectively. The first contact electrode 26 may be disposed on the first electrode 21, the second contact electrode 27 may be disposed on the second electrode 22, and the first and second contact electrodes 26 and 27 may extend in the second direction DR2. The first and second contact electrodes 26 and 27 may be spaced apart from, and face, each other in the first direction DR1 and may form stripe patterns in the emission area EMA of the first subpixel PX1.

[0129] In some embodiments, the width of the first and second contact electrodes 27 may be the same as, or smaller than, the width of the first and second electrodes 21 and 22. The first and second contact electrodes 26 and 27 may be disposed to be in electrical contact with both ends of each of the light-emitting elements 30 and to cover portions of the top surfaces of the first and second electrodes 21 and 22.

[0130] The contact electrodes (26 and 27) may be in electrical contact with the light-emitting elements 30 and the electrodes (21 and 22). The semiconductor layers included in each of the light-emitting elements 30 may be exposed at both ends of each of the light-emitting elements 30, and the first and second contact electrodes 26 and 27 may be in electrical contact with the light-emitting elements 30 at both ends of each of the light-emitting elements 30 where the semiconductor layers are exposed. The first ends of the light-emitting elements may be electrically connected to the first electrode 21 via the first contact electrode 26, and the second ends of the light-emitting elements 30 may be electrically connected to the second contact electrode 22 via the second contact electrode 27.

[0131] One first contact electrode 26 and one second contact electrode 27 are illustrated as being disposed in the first subpixel PX1, but the disclosure is not limited thereto. The numbers of first contact electrodes 26 and second contact electrodes 27 may vary depending on the numbers of first electrodes 21 and second electrodes 22 provided in the first subpixel PX1.

[0132] The third insulating layer 53 is disposed on the first contact electrode 26. The third insulating layer 53 may electrically insulate the first and second contact electrodes 26 and 27 from each other. The third insulating layer 53 may be disposed to cover or overlap the first contact electrode 26 but may not be disposed on the second ends of the light-emitting elements 30 so that the light-emitting elements 30 may be in electrical contact with the second contact electrode 27. The third insulating layer 53 may be in partial contact with the first and second contact electrodes 26 and 27 on the top surface of the second insulating layer 52. A side surface of the third insulating layer 53 adjacent to the second electrode 22 or where the second electrode 22 is disposed may be aligned with a corresponding side surface of the second insulating layer 52. The third insulating layer 53 may also be disposed in the non-emission area of the first subpixel PX1, for example, on the first insulating layer 51 on the first planarization layer 19, but the disclosure is not limited thereto.

[0133] The second contact electrode 27 is disposed on the second electrode 22, the second insulating layer 52, and the third insulating layer 53. The second contact electrode 27 may be in electrical contact with the second ends of the light-emitting elements 30 and an exposed portion of the top surface of the second electrode 22. The second ends of the light-emitting elements 30 may be electrically connected to the second electrode 22 via the second contact electrode 27.

[0134] The second contact electrode 27 may be in partial contact with the second insulating layer 52, the third insulating layer 53, the second electrode 22, and the light-emitting elements 30. The first and second contact electrodes 26 and 27 may not be in contact with the second and third insulating layers 52 and 53, but the disclosure is not limited thereto. In some embodiments, the

third insulating layer **53** may not be provided.

[0135] The contact electrodes (**26** and **27**) may include a conductive material. The contact electrodes (**26** and **27**) may include ITO, IZO, ITZO, or Al. For example, the contact electrodes (**26** and **27**) may include a transparent conductive material, and light emitted from the light-emitting elements **30** may travel toward the electrodes (**26** and **27**) through the contact electrodes (**26** and **27**). However, the disclosure is not limited to this.

[0136] A fourth insulating layer **54** may be disposed on the entire surface of the first substrate **11**. The fourth insulating layer **54** may protect elements disposed on the first substrate **11** from an external environment.

[0137] The first, second, third, and fourth insulating layers **51**, **52**, **53**, and **54** may include an inorganic insulating material or an organic insulating material. For example, the first, second, third, and fourth insulating layers **51**, **52**, **53**, and **54** may include an inorganic insulating material such as SiO.sub.x, SiN.sub.x, silicon oxynitride (SiO.sub.xN.sub.y), aluminum oxide (Al.sub.2O.sub.3), or aluminum nitride (AlN). In another example, the first, second, third, and fourth insulating layers **51**, **52**, **53**, and **54** may include an organic insulating material such as an acrylic resin, an epoxy resin, a phenolic resin, a polyamide resin, a polyimide resin, an unsaturated polyester resin, a polyphenylene resin, a polyphenylene sulfide resin, benzocyclobutene, a cardo resin, a siloxane resin, a silsesquioxane resin, polymethyl methacrylate, polycarbonate, or a polymethyl methacrylate-polycarbonate synthetic resin. However, the disclosure is not limited to these examples.

[0138] FIG. **6** is an enlarged schematic cross-sectional view of portion QA of FIG. **4**. FIG. **7** is a schematic cross-sectional view taken along line Q6-Q6' of FIG. **2**. Specifically, FIG. **6** illustrates an enlarged schematic cross-sectional view of portions where the first patterns **70** of FIG. **4** are disposed, and FIG. **7** illustrates a schematic cross-sectional view of light-emitting elements **30** arranged in the second direction DR2 together with first patterns **70** between the first banks **40**.

[0139] Referring to FIGS. **6** and **7** and further to FIGS. **3** through **5**, the first patterns **70** may be disposed between the first banks **40** to be spaced apart from one another in the second direction DR2. The first insulating layer **51**, which covers the first patterns **70**, is disposed to conform to the height differences generated by the first patterns **70**, which are disposed below the first insulating layer **51**, between the first banks **40**. During the fabrication of the display device **10**, ink including the light-emitting elements **30** may be sprayed into the first subpixel PX1 after the formation of the first insulating layer **51** and the second bank **45**. The light-emitting elements **30** may be sprayed onto the electrodes (**21** and **22**) while being scattered in the ink, and as the positions and the alignment direction of the light-emitting elements **30** change due to an electric field formed on the electrodes (**21** and **22**), the light-emitting elements **30** may be arranged so that both ends thereof may be placed on the electrodes (**21** and **22**).

[0140] The light-emitting elements **30**, scattered in the ink, may be randomly placed within the emission area EMA surrounded by the second bank **45** or may be placed even in regions other than regions between the first banks **40**. Light-emitting elements **30** placed in the regions other than regions between the first banks **40** may not be electrically connected to the electrodes (**21** and **22**) and may be lost during the fabrication of the display device **10**. If the light-emitting element loss rate is high, the process yield may decrease because of the need to spray a considerable amount of ink to maintain a predetermined number of light-emitting elements **30** in each subpixel PXn.

[0141] Since the top surfaces of the first banks **40** protrude from the first planarization layer **19**, the emission area EMA can be properly defined, and a considerable amount of light-emitting elements **30** can be guided to be placed within the space defined by the first banks **40**. Similarly, since the top surfaces of the first patterns **70** are elevated from the first planarization layer **19**, the region between the first banks **40** can be properly divided. The first insulating layer **51** can be located higher on the first patterns **70** than between the first patterns **70**, and the light-emitting elements **30**, scattered in the ink, can be guided into the regions where the first patterns **70** are spaced apart from

one another, in case that their positions change due to the electric field. For example, as illustrated in FIGS. 6 and 7, the first insulating layer 51 may be lower between the first patterns 70 than on the first patterns 70 with respect to the top surface of the first substrate 11 or the first planarization layer 19. Some of the light-emitting elements 30, scattered in the ink, may be guided to be disposed on portions of the first insulating layer 51 that are located relatively low.

[0142] The first patterns 70, like the first banks 40, can guide the light-emitting elements 30 to be placed at particular locations in the emission area EMA, and as a result, a considerable number of light-emitting elements 30 can be arranged between the first banks 40. Accordingly, the number of light-emitting elements 30 that may be lost during the fabrication of the display device 10 can be reduced, and the light-emitting elements 30 can be arranged so that both ends thereof can be placed on the electrodes (21 and 22), between the first banks 40. As a result, any contact defects between the contact electrodes (26 and 27) and the light-emitting elements 30 can be prevented.

[0143] The light-emitting elements 30 may include first light-emitting elements 30A that are disposed not to overlap the first patterns 70 in the thickness direction, and the first light-emitting elements 30A may be arranged so that both ends thereof may be placed on the first and second electrodes 21 and 22. The first light-emitting elements 30A may be aligned so that both ends thereof may be placed at desired locations. However, even if the light-emitting elements 30 are disposed on the first patterns 70, the light-emitting elements 30 can be electrically connected to the electrodes (21 and 22) as long as both ends thereof can be properly in electrical contact with the contact electrodes (26 and 27).

[0144] The light-emitting elements 30 may further include second light-emitting elements 30B that are disposed to overlap the first patterns 70 in the thickness direction. Most of the light-emitting elements 30, i.e., the first light-emitting elements 30A, may be disposed not to overlap the first patterns 70, but at least some of the light-emitting elements 30 may be disposed on the first patterns 70 to be in electrical contact with the contact electrodes (26 and 27). The second light-emitting elements 30B may be disposed on the first patterns 70 to be located higher than the first light-emitting elements 30A. The first light-emitting elements 30A may be located lower than the second light-emitting elements 30B with respect to the top surface of the first substrate 11 or the first planarization layer 19. The height difference between the first light-emitting elements 30A and the second light-emitting elements 30B may vary depending on the thickness of the first patterns 70.

[0145] The first patterns 70 may be thick enough to guide the light-emitting elements 30 to be arranged therebetween by the height differences generated between the first banks 40 by the first insulating layer 51. A thickness DP of the first patterns 70 may be greater than a thickness DE of the electrodes (21 and 22). The first insulating layer 51 may generate height differences between the first banks 40 with respect to the top surface of the first planarization layer 19 due to the presence of the electrodes (21 and 22). Portions of the first insulating layer 51 that cover the first and second electrodes 21 and 22 may be located higher than portions of the first insulating layer 51 that are disposed on the top surface of the first planarization layer 19. As the thickness DP of the first patterns 70 is greater than the thickness DE of the electrodes (21 and 22), portions of the first insulating layer 51 that are disposed on the first patterns 70 may be located higher than the portions of the first insulating layer 51 that are disposed on the first planarization layer 19 or the electrodes (21 and 22). The first patterns 70 can generate significant height differences between the first banks 40, and as a result, the light-emitting elements 30 can be guided to be placed at particular locations.

[0146] For example, a width W1 of the first patterns 70 may be smaller than a distance W3 between the first and second electrodes 21 and 22, and the first patterns 70 may be disposed between the first and second electrodes 21 and 22. The electrodes (21 and 22) may be disposed to be spaced apart from both side surfaces of each of the first patterns 70, and height differences generated between the electrodes (21 and 22) can effectively guide the light-emitting elements 30 to be placed at particular locations.

[0147] The width W1 of the first patterns 70 may be greater than a width W2 of the second

insulating layer 52. The second insulating layer 52 may be disposed to surround portions of the outer surfaces of the light-emitting elements 30 and thus to fix the light-emitting elements 30. The width W2 of the second insulating layer 52 may be smaller than a length h of the light-emitting elements 30 so that both ends of each of the light-emitting elements 30 may be exposed to be in electrical contact with the contact electrodes (26 and 27). The first patterns 70 may have such a predetermined width that even the second light-emitting elements 30B may be placed parallel to the top surface of the first planarization layer 19. If the width W1 of the first patterns 70 is too small, the first insulating layer 51, which is disposed on the first patterns 70, may not be able to provide sufficient space for the arrangement of the second light-emitting elements 30B, and the second light-emitting elements 30B may be slantingly arranged. The first patterns 70 may be formed to have a greater width than the second insulating layer 52 and may provide sufficient space for the arrangement of the second light-emitting elements 30B thereon.

[0148] However, the width W1 and the thickness DP of the first patterns 70 are not particularly limited. As another example, the width W1 of the first patterns 70 may be identical to or greater than the distance W3 between the first and second electrodes 21 and 22 and may be even greater than the length h of the light-emitting elements 30. The first patterns 70 and the first banks 40 may be formed at the same time, or the first patterns 70 may be formed by a separate patterning after the formation of the first banks 40. In some embodiments, the first patterns 70 may be integrally formed with the first planarization layer 19, which is disposed below the first patterns 70.

[0149] The display device 10 may include first patterns 70 that are arranged in one direction between the first banks 40. During the fabrication of the display device 10, most of the light-emitting elements 30 can be guided to be aligned at particular locations, and the number of light-emitting elements 30 that may be lost from each subpixel PXn can be minimized.

[0150] FIG. 8 is a schematic partial cross-sectional view of a display device according to another embodiment of the disclosure. FIG. 8, similar to FIG. 4, illustrates a schematic cross-sectional view of first patterns 70 with no light-emitting elements 30 disposed thereon.

[0151] Referring to FIG. 8, a display device 10 may not include the third insulating layer 53 of FIG. 4. A second contact electrode 27 may be disposed directly on portion of a second insulating layer 52, and first and second contact electrodes 26 and 27 may be spaced apart from each other over the second insulating layer 52. Even though the display device 10 does not include the third insulating layer 53, the second insulating layer 52 includes an organic insulating material and may fix a light-emitting element 30. The first and second contact electrodes 26 and 27 may be formed at the same time by a patterning process. The embodiment of FIG. 8 is almost the same as the embodiment of FIG. 4 except that the third insulating layer 53 is not provided, and thus, a detailed description thereof will be omitted.

[0152] FIG. 9 is a schematic perspective view of a light-emitting element according to an embodiment of the disclosure.

[0153] Referring to FIG. 9, a light-emitting element 30 may be a light-emitting diode (LED), particularly, an ILED having a size of several micrometers or nanometers and formed of an inorganic material. If an electric field is formed in a particular direction between two opposite electrodes, the ILED may be aligned between the two electrodes where polarities are formed. The light-emitting element 30 may be aligned by the electric field formed between the two electrodes.

[0154] The light-emitting element 30 may have a shape that extends in one direction. The light-emitting element 30 may have the shape of a rod, a wire, or a tube. For example, the light-emitting element 30 may have a cylindrical or rod shape, but the disclosure is not limited thereto. In another example, the light-emitting element 30 may have the shape of a polygonal column such as a regular cube, a rectangular parallelepiped, or a hexagonal column or may have a shape that extends in one direction and has a partially inclined outer surface. Semiconductors included in the light-emitting element 30 may be sequentially disposed or stacked in the direction in which the light-emitting element 30 extends.

[0155] The light-emitting element **30** may include semiconductor layers doped with impurities of an arbitrary conductivity type (e.g., a p-type or an n-type). The semiconductor layers may receive electrical signals from an external power source to emit light of a particular wavelength range.

[0156] Referring to FIG. **9**, the light-emitting element **30** may include a first semiconductor layer **31**, a second semiconductor layer **32**, a light-emitting layer **36**, an electrode layer **37**, and an insulating film **38**.

[0157] The first semiconductor layer **31** may include an n-type semiconductor. For example, in a case where the light-emitting element **30** emits light of a blue wavelength range, the first semiconductor layer **31** may include a semiconductor material $\text{Al}_{0.1}\text{Ga}_{0.9}\text{In}_{0.1}\text{N}$ (where $0 \leq x \leq 1$, $0 \leq y \leq 1$, and $0 \leq x + y \leq 1$). For example, the semiconductor material $\text{Al}_{0.1}\text{Ga}_{0.9}\text{In}_{0.1}\text{N}$ may be at least one of AlGaInN, GaN, AlGaIn, InGaIn, AlIn, and InN that are doped with an n-type dopant. The first semiconductor layer **31** may be doped with an n-type dopant, and the n-type dopant may be, for example, Si, Ge, or Sn. For example, the first semiconductor layer **31** may be n-GaN doped with n-type Si. The first semiconductor layer **31** may have a length of about 1.5 μm to about 5 μm , but the disclosure is not limited thereto.

[0158] The second semiconductor layer **32** is disposed on the light-emitting layer **36**. The second semiconductor layer **32** may include a p-type semiconductor. For example, in a case where the light-emitting element **30** emits light of a blue or green wavelength range, the second semiconductor layer **32** may include a semiconductor material $\text{Al}_{0.1}\text{Ga}_{0.9}\text{In}_{0.1}\text{N}$ (where $0 \leq x \leq 1$, $0 \leq y \leq 1$, and $0 \leq x + y \leq 1$). For example, the semiconductor material $\text{Al}_{0.1}\text{Ga}_{0.9}\text{In}_{0.1}\text{N}$ may be at least one of AlGaInN, GaN, AlGaIn, InGaIn, AlIn, and InN that are doped with a p-type dopant. The second semiconductor layer **32** may be doped with a p-type dopant, and the p-type dopant may be, for example, Mg, Zn, Ca, Se, or Ba. For example, the second semiconductor layer **32** may be p-GaN doped with p-type Mg. The second semiconductor layer **32** may have a length of about 0.05 μm to about 0.10 μm , but the disclosure is not limited thereto.

[0159] The first and second semiconductor layers **31** and **32** are illustrated as being formed as single-layer films, but the disclosure is not limited thereto. As another example, each of the first and second semiconductor layers **31** and **32** may include more than one layer such as, for example, a clad layer or a tensile strain barrier reducing (TSBR) layer, depending on the material of the light-emitting layer **36**.

[0160] The light-emitting layer **36** is disposed between the first and second semiconductor layers **31** and **32**. The light-emitting layer **36** may include a single-or multi-quantum well structure material. In a case where the light-emitting layer **36** includes a material having a multi-quantum well structure, the light-emitting layer **36** may have a structure in which multiple quantum layers and multiple well layers are alternately stacked. The light-emitting layer **36** may emit light by combining electron-hole pairs in accordance with electrical signals applied thereto via the first and second semiconductor layers **31** and **32**. For example, in a case where the light-emitting layer **36** emits light of a blue wavelength range, the quantum layers may include a material such as AlGaIn or AlGaInN. In particular, in a case where the light-emitting layer **36** has a multi-quantum well structure in which multiple quantum layers and multiple well layers are alternately stacked, the quantum layers may include a material such as AlGaIn or AlGaInN, and the well layers may include a material such as GaN or AlInN. In a case where the light-emitting layer **36** includes AlGaInN as its quantum layer(s) and AlInN as its well layer(s), the light-emitting layer **36** can emit blue light having a central wavelength range of about 450 nm to about 495 nm.

[0161] However, the disclosure is not limited to this. As another example, the light-emitting layer **36** may have a structure in which a semiconductor material having a large band gap energy and a semiconductor material having a small band gap energy are alternately stacked or may include group III or group V semiconductor materials depending on the wavelength of light to be emitted. The type of light emitted by the light-emitting layer **36** is not particularly limited. The light-

emitting layer **36** may emit light of a red or green wavelength range as necessary, instead of blue light. The light-emitting layer **36** may have a length of about 0.05 μm to about 0.10 μm , but the disclosure is not limited thereto.

[0162] Light may be emitted not only from the circumferential surface, in a length direction, of the light-emitting element **30**, but also from both sides of the light-emitting element **30**. The directionality of the light emitted from the light-emitting layer **36** is not particularly limited.

[0163] The electrode layer **37** may be an ohmic contact electrode, but the disclosure is not limited thereto. As another example, the electrode layer **37** may be a Schottky contact electrode. The light-emitting element **30** may include at least one electrode layer **37**. FIG. **9** illustrates that the light-emitting element **30** includes one electrode layer **37**, but the disclosure is not limited thereto. As another example, the light-emitting element **30** may include more than one electrode layer **37**, or the electrode layer **37** may not be provided. However, the following description of the light-emitting element **30** may be directly applicable to a light-emitting element **30** having more than one electrode layer **37** or having a different structure from the light-emitting element **30** of FIG. **9**.

[0164] The electrode layer **37** may reduce the resistance between the light-emitting element **30** and electrodes (or contact electrodes) in case that the light-emitting element **30** is electrically connected to the electrodes (or the contact electrodes). The electrode layer **37** may include a conductive metal. For example, the electrode layer **37** may include at least one of Al, Ti, In, Au, Ag, ITO, IZO, and ITZO. Also, the electrode layer **37** may include a semiconductor material doped with an n-or p-type dopant. The electrode layer **37** may include the same material or different materials, but the disclosure is not limited thereto.

[0165] The insulating film **38** is disposed to surround the first and second semiconductor layers **31** and **32** and the electrode layer **37**. For example, the insulating film **38** may be disposed to surround at least the light-emitting layer **36** and may extend in the direction in which the light-emitting element **30** extends. The insulating film **38** may protect the first semiconductor layer **31**, the light-emitting layer **36**, the second semiconductor layer **32**, and the electrode layer **37**. For example, the insulating film **38** may be formed to surround the sides of the first semiconductor layer **31**, the light-emitting layer **36**, the second semiconductor layer **32**, and the electrode layer **37**, but to expose both ends, in the length direction, of the light-emitting element **30**.

[0166] The insulating film **38** is illustrated as being formed to extend in the length direction of the light-emitting element **30** and to cover the sides of the first semiconductor layer **31**, the light-emitting layer **36**, the second semiconductor layer **32**, and the electrode layer **37**, but the disclosure is not limited thereto. The insulating film **38** may cover the sides of only the light-emitting layer **36** and some of the first and second semiconductor layers **31** and **32** or may cover only portion of the side of the electrode layer **37** so that the side of the electrode layer **37** may be partially exposed. The insulating film **38** may be formed to be rounded in a cross-sectional view, in a region adjacent to at least one end of the light-emitting element **30**.

[0167] The insulating film **38** may have a thickness of about 10 nm to about 1.0 μm , but the disclosure is not limited thereto. The insulating film **38** may have a thickness of about 40 nm.

[0168] The insulating film **38** may include a material with insulating properties such as, for example, $\text{SiO}_{\text{sub.x}}$, $\text{SiN}_{\text{sub.x}}$, $\text{SiO}_{\text{sub.x}}\text{N}_{\text{sub.y}}$, AlN, or $\text{Al}_{\text{sub.2}}\text{O}_{\text{sub.3}}$. Accordingly, the insulating film **38** can prevent any short circuit that may occur in case that the light-emitting layer **36** is placed in direct contact with electrodes that transmit electrical signals directly to the light-emitting element **30**. Since the insulating film **38** includes the light-emitting layer **36** to protect the outer surface of the light-emitting element **30**, any degradation in the emission efficiency of the light-emitting element **30** can be prevented.

[0169] In some embodiments, the outer surface of the insulating film **38** may be subjected to surface treatment. The light-emitting element **30** may be sprayed on electrodes while being scattered in predetermined ink. Here, the surface of the insulating film **38** may be hydrophobically or hydrophilically treated to keep the light-emitting element **30** scattered in ink without

agglomerating with other neighboring light-emitting elements **30**.

[0170] A length h of the light-emitting element **30** may be in the range of about 1 μm to about 10 μm , about 2 μm to about 6 μm , or about 3 μm to about 5 μm . The light-emitting element **30** may have a diameter of about 30 nm to about 700 nm and may have an aspect ratio of 1.2 to 100, but the disclosure is not limited thereto. Different light-emitting elements **30** included in the display device **10** may have different diameters depending on the composition of their respective light-emitting layers **36**. For example, the light-emitting element **30** may have a diameter of about 500 nm.

[0171] A method of fabricating the display device **10** will hereinafter be described.

[0172] FIGS. **10** through **12** are schematic cross-sectional views illustrating processes of a method of fabricating a display device according to an embodiment of the disclosure. FIG. **13** is a schematic plan view of a subpixel obtained by the process(es) illustrated in FIG. **12**.

[0173] Referring first to FIG. **10**, a target substrate SUB where a first insulating layer **51** and electrodes (**21** and **22**) are disposed is prepared. Although not specifically illustrated, the target substrate SUB may include a first substrate **11** and may further include circuit elements that include conductive layers and insulating layers. For convenience, the first substrate **11** and the circuit elements will hereinafter be collectively referred to as the target substrate SUB.

[0174] Thereafter, first banks **40** are formed on the target substrate SUB to be spaced apart from each other. As already mentioned above, the first banks **40** may protrude from the top surface of the target substrate SUB.

[0175] Thereafter, referring to FIG. **11**, first patterns **70** are formed between the first banks **40**, on the target substrate SUB. The first patterns **70** may be spaced apart from the first banks **40** and may have a smaller thickness than the first banks **40**. The first patterns **70** are illustrated as being formed after the formation of the first banks **40**, but the disclosure is not limited thereto. As another example, the first patterns **70** and the first banks **40** may include the same materials and may be formed at the same time. For example, the first banks **40** and the first patterns **70**, which have a different thickness from the first banks **40**, may be formed at the same time using a halftone mask during the formation of the first banks **40**.

[0176] Thereafter, referring to FIGS. **12** and **13**, first and second electrode layers **21'** and **22'** are formed on the first banks **40**. The first and second electrode layers **21'** and **22'** extend in a second direction DR2 and are spaced apart from each other with the first patterns **70** therebetween. The first and second electrode layers **21'** and **22'** may extend in the second direction DR2 to be disposed in other subpixels PXn during the fabrication of a display device **10**. The first and second electrode layers **21'** and **22'** may be cut in a cut area CBA of each subpixel PXn after the arrangement of light-emitting elements **30** and may then be formed into first and second electrodes **21** and **22**, respectively.

[0177] The first patterns **70** may be arranged between the first banks **40** or between the first and second electrode layers **21'** and **22'** to be spaced apart from one another in the second direction DR2. The region between the first banks **40** may be divided into regions where the first patterns **70** are disposed and regions where the first patterns **70** are not disposed, and the regions where the first patterns **70** are disposed may have a different height from the regions where the first patterns **70** are not disposed. Thereafter, a first insulating layer **51**, which covers the first patterns **70** and the first and second electrode layers **21'** and **22'**, and a second bank **45**, which is disposed on the first insulating layer **51**, are formed, and the light-emitting elements **30** are disposed between the first banks **40**.

[0178] FIGS. **14** and **15** are schematic cross-sectional views illustrating processes of the method of fabricating a display device according to an embodiment of the disclosure.

[0179] Referring to FIGS. **14** and **15**, a first insulating material layer **51'**, which covers the first patterns **70** and electrode layers (**21'** and **22'**), is formed, and the second bank **45**, which is disposed on the first insulating material layer **51'** and surrounds an emission area EMA and the cut area CBA of each subpixel PXn, is formed. The first insulating material layer **51'** may be disposed on the

entire surface of the target substrate SUB and may cover the first patterns **70** and the electrode layers (**21'** and **22'**). The first insulating material layer **51'** may be partially removed in a subsequent process so that the top surfaces of the electrode layers (**21'** and **22'**) may be exposed, and as a result, the first insulating layer **51** may be formed. As already mentioned above, the second bank **45** may be disposed to surround and separate each subpixel PXn and may also separate the emission area EMA and the cut area CBA of each subpixel PXn.

[0180] FIG. **16** is a schematic plan view of a subpixel obtained by the processes illustrated in FIGS. **14** and **15**. FIGS. **17** through **19** are schematic cross-sectional views illustrating the arrangement of light-emitting elements and first patterns in the subpixel of FIG. **16**. Specifically, FIG. **17** illustrates light-emitting elements **30** disposed in regions where first patterns **70** are not disposed, and FIG. **18** illustrates light-emitting elements **30** disposed in regions where the first patterns **70** are disposed. FIG. **19** illustrates light-emitting elements **30** disposed between the first patterns **70**, which are spaced apart from each other in the second direction DR2.

[0181] Referring to FIGS. **16** through **19**, light-emitting elements **30** are disposed between the first banks **40**. The light-emitting elements **30** may be disposed so that both ends thereof may be placed on the first and second electrode layers **21'** and **22'**. The light-emitting elements **30** may be sprayed onto the target substrate SUB while being scattered in ink. For example, the light-emitting elements **30** may be prepared to be scattered in ink and may then be sprayed onto the target substrate SUB by a printing process using an inkjet printing device. The ink sprayed by the inkjet printing device may be settled within each region surrounded by the second bank **45**. The second bank **45** may prevent the ink from spilling over between different pixels PXn.

[0182] Once the ink including the light-emitting elements **30** is sprayed, the light-emitting elements **30** may be arranged on the first insulating material layer **51'** by applying electrical signals to the electrode layers (**21'** and **22'**). As the electrical signals are applied to the electrode layers (**21'** and **22'**), an electric field may be generated between the electrode layers (**21'** and **22'**). The light-emitting elements **30** scattered in the ink may receive a dielectrophoretic force from the electric field, and as a result, the alignment direction and the positions of the light-emitting elements **30** may change so that the light-emitting elements **30** may be settled on the first insulating material layer **51'**. Here, some of the light-emitting elements **30**, i.e., light-emitting elements **30A**, may be disposed between the first patterns **70**, as illustrated in FIG. **17**, and some of the light-emitting elements **30**, e.g., light-emitting elements **30B**, may be disposed on the first patterns **70**, as illustrated in FIG. **18**. Also, some of the first patterns **70** may have no light-emitting elements **30** disposed thereon. The first patterns **70** may guide the light-emitting elements **30** to be placed so that each of both ends of each of the light-emitting elements **30** may be arranged on corresponding one of electrodes (**21** and **22**) or on the electrode layers (**21'** and **22'**), and most of the light-emitting elements **30** may be arranged at locations relatively lower than the first patterns **70**. However, as illustrated in FIG. **5**, at least some of the light-emitting element **30** may be disposed on the first patterns **70**, and even these light-emitting elements **30** may be electrically connected to the electrodes (**21** and **22**) via contact electrodes (**26** and **27**).

[0183] FIGS. **20** and **21** are schematic cross-sectional views illustrating processes of the method of fabricating a display device according to an embodiment of the disclosure. Specifically, FIGS. **20** and **21** illustrate schematic cross-sectional views of first patterns **70** having no light-emitting elements **30** disposed thereon.

[0184] Referring to FIG. **21**, the first insulating layer **51** may be formed by removing portions of the first insulating material layer **51'** to expose the top surfaces of the first and second electrode layers **21'** and **22'**. The first insulating layer **51** may include openings OP, which expose portions of the electrode layers (**21'** and **22'**). The top surfaces of the electrode layers (**21'** and **22'**), exposed by the openings OP, may be in electrical contact with the contact electrodes (**26** and **27**).

[0185] Thereafter, the first and second electrodes **21** and **22** are formed by cutting the first and second electrode layers **21'** and **22'** in the cut area CBA of each subpixel PXn, and a second

insulating layer **52**, a third insulating layer **53**, and the contact electrodes (**26** and **27**) are formed on the light-emitting elements **30**. Electrical signals for the alignment of the light-emitting elements **30** may be applied to the electrode layers (**21'** and **22'**) electrically connected to each subpixel PXn. For the driving of the display device **10**, however, the electrode layers (**21'** and **22'**) may be cut and separated in the cut area CBA of each subpixel PXn, thereby forming the electrodes (**21** and **22**), and as a result, the electrodes (**21** and **22**) can be driven separately via a first transistor TR1 of each subpixel PXn.

[0186] Thereafter, although not specifically illustrated, a fourth insulating layer **54**, which covers the elements disposed on the target substrate SUB, may be formed, thereby fabricating the display device **10**.

[0187] Display devices according to other embodiments of the disclosure will hereinafter be described.

[0188] A display device **10** includes first patterns **70**, which are disposed between first banks **40**, in each subpixel PXn. FIG. **6** illustrates that the width W1 of the first patterns **70** is smaller than the distance W3 between the electrodes (**21** and **22**), but the disclosure is not limited thereto. For example, the width W1 and the thickness DP of the first patterns **70** may vary as long as the light-emitting elements **30** can be properly guided to be aligned at particular locations.

[0189] FIGS. **22** through **24** are schematic partial cross-sectional views of display devices according to other embodiments of the disclosure. Specifically, FIGS. **22** and **23** illustrate schematic cross-sectional views of first patterns **70_1** or **70_2** having no light-emitting elements **30** disposed thereon, and FIG. **24** illustrate a schematic cross-sectional view of first patterns **70_3** having second light-emitting elements **30B** disposed thereon.

[0190] Referring to FIG. **22**, a width W1 of first patterns **70_1** may be the same as a distance W3 between electrodes (**21_1** and **22_1**), and the first patterns **70_1** may be in electrical contact with the electrodes (**21_1** and **22_1**). The first patterns **70_1** may be formed to have a relatively large width W1 and to be in electrical contact with the electrodes (**21_1** and **22_1**), and a first insulating layer **51**, which is disposed on the first patterns **70_1**, may provide space in which second light-emitting elements **30B** can be horizontally arranged.

[0191] Referring to FIG. **23**, a width W1 of first patterns **70_2** may be greater than a distance W3 between electrodes (**21_2** and **22_2**), and first sides of the electrodes (**21_2** and **22_2**) may be disposed on the first patterns **70_2**. The embodiment of FIG. **23** differs from the other embodiments at least in that the first sides of the electrodes (**21_2** and **22_2**) are disposed on the first patterns **70_2** because of the first patterns **70_2** having a relatively large width W1. Although not specifically illustrated, second light-emitting elements **30B** disposed on the first patterns **70_2** may be arranged so that both ends thereof may be placed on the electrodes (**21_2** and **22_2**), and as a result, the second light-emitting elements **30B** can be properly in electrical contact with contact electrodes (**26** and **27**). In the embodiment of FIG. **23**, unlike in the embodiment of FIG. **5**, the number of light-emitting elements **30** electrically connected to the electrodes (**21_2** and **22_2**), between first banks **40**, can be further increased.

[0192] In case that first patterns **70** have a relatively small width, second light-emitting elements **30B** may not be able to be properly in electrical contact with contact electrodes (**26** and **27**). Light-emitting elements **30** may be inclined, rather than being horizontally arranged, depending on the width of the first patterns **70**, and electrical signals may not be able to be properly transmitted to the light-emitting elements **30** due to contact defects. By controlling the thickness of the first patterns **70**, the light-emitting elements **30** can be guided to be placed between the first patterns **70**, rather than on the first patterns **70**, in case that the light emitting elements **30** are aligned by an electric field.

[0193] Referring to FIG. **24**, a thickness DP_3 of first patterns **70_3** may be greater than a thickness DE of electrodes (**21** and **22**), but smaller than a diameter DN of light-emitting elements **30**. In case that the thickness DP_3 of the first patterns **70_3** is smaller than the diameter DN of the

light-emitting elements **30**, the light-emitting elements **30** can be easily moved away from above the first patterns **70_3** by an electric field during the fabrication of a display device **10**. If an electric field is generated for aligning the light-emitting elements **30** and is continued for more than a predetermined amount of time, light-emitting elements **30** disposed on the first patterns **70_3** may be moved to locations where the first patterns **70_3** are not disposed. Even light-emitting elements **30** disposed in regions other than that between first banks **40** can be moved over the first patterns **70_3**. Second light-emitting elements **30B** are illustrated as being disposed on the first patterns **70_3**, but in an embodiment, a considerable number of light-emitting elements **30**, similar to first light-emitting elements **30A**, can be disposed not to overlap the first patterns **70_3**. Since the first patterns **70_3** have a smaller thickness **DP_3** than the diameter **DN** of the light-emitting elements **30**, most of the light-emitting elements **30** can be arranged similar to the first light-emitting elements **30A**. For example, the thickness **DP_3** of the first patterns **70_3** may be smaller than half the diameter **DN** of the light-emitting elements **30**.

[0194] The shape of first patterns **70** may vary as long as the first patterns **70** can generate height differences between first banks **40** and can properly guide light-emitting elements **30** to be placed at particular locations. For example, the shape of the first patterns **70** may vary as long as at least some light-emitting elements **30** electrically connected to first and second electrodes **21** and **22** can be located higher or lower than other light-emitting elements **30**.

[0195] FIGS. **25** and **26** are schematic partial cross-sectional views of display devices according to other embodiments of the disclosure.

[0196] Specifically, FIG. **25** illustrates a schematic cross-section view of first patterns **70_4** with no light-emitting elements **30** disposed thereon. Referring to FIG. **25**, the first patterns **70_4** may be integrally formed with (or integral with) a first planarization layer **19**, which is disposed below the first patterns **70_4**. During the formation of the first planarization layer **19**, portions of the top surface of the first planarization layer **19** may be formed to protrude and thus to form the first patterns **70_4**. The first patterns **70_4** may be formed in various processes during the fabrication of a display device **10**. As already mentioned above, the first patterns **70_4** may be formed during or after the formation of the first banks **40**, and the first patterns **70_4** may be formed by making portions of the top surface of the first planarization layer **19** protrude. The embodiment of FIG. **25** differs from the embodiment of FIG. **5** at least in that the first patterns **70_4** are integrally formed with the first planarization layer **19**. The first planarization layer **19** may include the first patterns **70_4**, which are formed as protrusions from the top surface of the first planarization layer **19**, and portions where the first patterns **70_4** are not formed. Among light-emitting elements **30**, first light-emitting elements **30A** may be disposed on the portions of the first planarization layer **19** where the first patterns **70_4** are not formed, and second light-emitting elements **30B** may be disposed on the first patterns **70_4**. Most of the light-emitting elements **30** can be guided to be placed between the first patterns **70_4**, rather than on the first patterns **70_4**, during the fabrication of the display device **10**.

[0197] Referring to FIG. **26**, a first planarization layer **19_5** may include recesses where portions the top surface of the first planarization layer **19_5** are depressed between first banks **40**, and at least some of light-emitting elements **30** may be disposed in the recesses. During the formation of the first planarization layer **19_5**, the recesses may be formed between the first banks **40**. During the fabrication of a display device **10**, a process of generating height differences may be performed to allow the light-emitting elements **30** to be placed at different locations. For example, after the formation of the first planarization layer **19_5**, the recesses may be formed between the first banks **40** during the formation of first and second contact holes **CT1** and **CT2**. As the recesses are formed between the first banks **40**, height differences are generated in a second direction **DR2**, and the light-emitting elements **30** disposed between the first banks **40** may be arranged to have different heights from the top surface of a first substrate **11**. The embodiment of FIG. **26** differs from the other embodiments at least in that portions of the top surface of the first planarization layer **19_5**

are depressed.

[0198] For example, a width **W4** of the recesses may be greater than a distance **W3** between electrodes (**21_5** and **22_5**), and at least a portion of the electrodes (**21_5** and **22_5**) may be disposed in the recesses. The light-emitting elements **30** can be guided to be moved into the recesses by an electric field, and some or most of the light-emitting elements **30** can be disposed in the recesses. First light-emitting elements **30A** are illustrated as being disposed in the recesses, but the disclosure is not limited thereto. The light-emitting elements **30** may further include second light-emitting elements **30B**, which are disposed on portions of the first planarization layer **19_5** where the recesses are not formed and are located higher than the first light-emitting elements **30A**. [0199] The shape of the first patterns **70**, **70_1**, **70_2**, **70_3**, and **70_4** is not particularly limited. The first patterns **70**, **70_1**, **70_2**, **70_3**, and **70_4** are illustrated as having a rectangular shape in a plan view or a cross-sectional view, but the disclosure is not limited thereto.

[0200] FIG. **27** is a schematic partial cross-sectional view of a display device according to another embodiment of the disclosure. FIG. **28** is a schematic plan view of a subpixel of the display device of FIG. **27**.

[0201] Referring to FIGS. **27** and **28**, the top surfaces of first patterns **70_6** may be curved. In some embodiments, the first patterns **70_6** may have a hemispherical shape and/or may be circular in a plan view and semicircular in a cross-sectional view. Portions of a first insulating layer **51_6** on the first patterns **70_6** may not have a flat top surface, and the positions of light-emitting elements **30** disposed on the portions of the first insulating layer **51_6** may be changed by an electric field so that the light-emitting elements **30** may not overlap the first patterns **70_6**. As a result, the light-emitting elements **30** may not be disposed on the first patterns **70_6**, and portions of a second insulating layer **52_6** that overlap the first patterns **70_6** may be in direct contact with the first insulating layer **51_6**. The embodiment of FIGS. **27** and **28** differs from the other embodiments at least in that the first patterns **70_6** may have a curved top surface and only first light-emitting elements **30A** (and no second light-emitting elements **30B**) are provided.

[0202] FIG. **29** is a schematic plan view of a subpixel of a display device according to another embodiment of the disclosure. FIG. **30** is a schematic cross-sectional view taken along line QB-QB' of FIG. **29**. FIG. **31** is a schematic plan view of a subpixel of a display device according to another embodiment of the disclosure. FIG. **32** is a schematic cross-sectional view taken along lines QC-QC', QD-QD', and QE-QE' of FIG. **31**. FIGS. **30** and **32** illustrate schematic cross-sectional views, taken in a second direction DR2, of first patterns **70_7** and light-emitting elements **30**.

[0203] Referring to FIGS. **29** through **32**, first patterns **70_7** or **70_8** may be disposed to overlap a first electrode **21** or a second electrode **22**. The first patterns **70_7** or **70_8** may be disposed directly on a first planarization layer **19** where the first and second electrodes **21** and **22** are disposed and may generate height differences in the first and second electrodes **21** and **22**. The first patterns **70_7** or **70_8** may have such a small width that light-emitting elements **30** can be easily moved away from the first patterns **70_7** or **70_8** even if they are disposed on the first patterns **70_7** or **70_8**, and may be disposed to overlap electrodes (**21** and **22**). In the embodiments of FIGS. **29** through **32**, unlike in an embodiment where the first patterns **70_7** or **70_8** are disposed between the electrodes (**21** and **22**), some or most of the light-emitting elements **30** (e.g., first light-emitting elements **30A** of FIGS. **30** and **32**) can be disposed not to overlap the first patterns **70_7** or **70_8** because height differences are generated in portions of the electrodes (**21** and **22**) where the ends of the light-emitting elements **30** are disposed.

[0204] In some embodiments, first patterns **70_7** or **70_8** that overlap the first electrode **21** and first patterns **70_7** or **70_8** that overlap the second electrode **22** may be arranged either parallel to each other or in a staggered manner between first banks **40**. For example, as illustrated in FIGS. **29** and **30**, the first patterns **70_7** or **70_8** that overlap the first electrode **21** and the first patterns **70_7** or **70_8** that overlap the second electrode **22** may be arranged parallel to each other between the first banks **40**. In another example, as illustrated in FIGS. **31** and **32**, the first patterns **70_7** or **70_8** that

overlap the first electrode **21** and the first patterns **70_7** or **70_8** that overlap the second electrode **22** may be arranged in a staggered manner between the first banks **40**.

[0205] During the fabrication of a display device **10**, even if first ends of the light-emitting elements **30** are disposed on the first patterns **70_7** or **70_8**, second ends of the light-emitting elements **30** may not be disposed on the first patterns **70_7** or **70_8**, or vice versa. In this case, in the presence of an electric field, the light-emitting elements **30** can be moved to regions where the first patterns **70_7** or **70_8** are not formed. Since the first patterns **70_7** or **70_8** have a relatively small width and are disposed to overlap the electrodes (**21** and **22**), the light-emitting elements **30** can be properly guided toward locations where the first patterns **70_7** or **70_8** are not disposed, even if ends of the light-emitting elements **30** are disposed on the first patterns **70_7** or **70_8**.

[0206] The first and second electrodes **21** and **22** may not necessarily extend in one direction. In some embodiments, the electrodes (**21** and **22**) may include portions that extend in one direction to have different widths and portions that extend in another direction.

[0207] FIG. **33** is a schematic plan view of a subpixel of a display device according to another embodiment of the disclosure.

[0208] Referring to FIG. **33**, each of electrodes (**21_9** and **22_9**) may include an extended portion RE-E, which generally extends in a second direction and has a greater width than the rest of the corresponding electrode, bent portions (RE-B1 and RE-B2), which extend in a diagonal direction with respect to a first direction DR1 or the second direction DR2, and connecting portions (RE-C1 and RE-C2), which connect the bent portions (RE-B1 and RE-B2) and the extended portion RE-E. The electrodes (**21_9** and **22_9**) may generally extend in the second direction DR2 but may have a relatively large width in portion or may be bent in a diagonal direction with respect to the second direction DR2. First and second electrodes **21_9** and **22_9** may be arranged symmetrically with respect to a first pattern **70_9** disposed therebetween. The shape of the first electrode **21_9** will hereinafter be described.

[0209] The first electrode **21_9** may include an extended portion RE-E, which has a greater width than the rest of the first electrode **21_9**. Extended portions RE-E of the first and second electrodes **21_9** and **22_9** may be disposed on first banks **40**, in an emission area EMA of a first subpixel PX1, to extend in the second direction DR2. The first pattern **70_9** may be disposed between the extended portions RE-E, and light-emitting elements **30** may be disposed on the extended portions RE-E. First and second contact electrodes **26_9** and **27_9** may be disposed on the extended portions RE-E but may have a smaller width than the extended portions RE-E.

[0210] Connecting portions (RE-C1 and RE-C2) may extend or be connected to both sides, in the second direction DR2, of each of the extended portion RE-E. First connecting portions RE-C1 may be disposed on first sides, in the second direction DR2, of the extended portions RE-E, and second connecting portions RE-C2 may be disposed on second sides, in the second direction DR2, of the extended portions RE-E. The connecting portions (RE-C1 and RE-C2) may extend or be connected to the extended portions RE-E of the corresponding electrode and may be disposed in and across the emission area EMA and a second bank **45**.

[0211] The first connecting portions RE-C1 and the second connecting portions RE-C2 may have a smaller width than the extended portions RE-E. First sides of the connecting portions (RE-C1 and RE-C2) that extend in the second direction DR2 may extend or be connected to, and fall on the same line as, a first side of the respective extended portion RE-E that extends in the second direction DR2. For example, an outer side of the extended portion RE-E of each of the electrodes (**21_9** and **22_9**) may extend to be electrically connected to outer sides of the connecting portions (RE-C1 and RE-C2) of the corresponding electrode. Accordingly, a distance DE1 between the extended portions RE-E of the first and second electrodes **21_9** and **22_9** may be smaller than a distance DE2 between the connecting portions (RE-C1 and RE-C2) of the first and second electrodes **21_9** and **22_9**.

[0212] Bent portions (RE-B1 and RE-B2) extend or are connected to the connecting portions (RE-

C1 and RE-C2). The bent portions (RE-B1 and RE-B2) may include first bent portions RE-B1, which extend or are connected to first connecting portions RE-C1 and are disposed on the second bank 45 and in a cut area CBA, and second bent portions RE-B2, which extend or are connected to second connecting portions RE-C2 and are disposed on the second bank 45 and in a cut area CBA of another subpixel PXn. The bent portions (RE-B1 and RE-B2) may be electrically connected to the connecting portions (RE-C1 and RE-C2) and may be bent in a diagonal direction with respect to the second direction DR2, for example, in a direction toward the center of the first subpixel PX1. A minimum distance DE3 between the bent portions (RE-B1 and RE-B2) may be smaller than the distance DE2 between the connecting portions (RE-C1 and RE-C2) but may be greater than the distance DE1 between the extended portions RE-E.

[0213] Contact portions RE-P may be formed in regions where the first connecting portions RE-C1 and the first bent portions RE-B1 are electrically connected. The contact portions RE-P may overlap the second bank 45 so that first and second contact holes CT1 and CT2 of the first and second electrodes 21_9 and 22_9 may be formed.

[0214] Fragment portions RE-D, which are obtained when the first and second electrodes 21_9 and 22_9 are separated into pieces in the cut area CBA, may be formed at first ends of the first bent portions RE-B1. The fragment portions RE-D may be portions of first and second electrodes 21_9 and 22_9 of a neighboring subpixel PXn in the second direction DR2 that remain in the cut area CBA.

[0215] The embodiment of FIG. 33 differs from the embodiment of FIG. 4 at least in that each of the first and second electrodes 21_9 and 22_9 includes an extended portions RE-E, connecting portions (RE-C1 and RE-C2), and bent portions (RE-B1 and RE-B2) and are arranged symmetrically with respect to the center of the first subpixel PX1. However, the disclosure is not limited to this. As another example, the first and second electrodes 21_9 and 22_9 may have different shapes.

[0216] FIG. 34 is a schematic plan view of a subpixel of a display device according to another embodiment of the disclosure. FIG. 35 is a schematic cross-sectional view taken along line QX-QX' of FIG. 34.

[0217] Referring to FIGS. 34 and 35, a display device 10 may include, in each subpixel PXn thereof, for example, in a first subpixel PX1, first electrodes 21_10, second electrodes 22_10, and first patterns 70_10. The first electrodes 21_10 may have the same shape as their counterpart of FIG. 28, and first electrodes 21_10, for example, two first electrodes 21_10, may be arranged symmetrically with respect to the center of the first subpixel PX1. The second electrodes 22_10 may have the same shape as their counterpart of FIG. 2, and second electrodes 22_10, for example, two second electrodes 22_10, may be arranged between the first electrodes 21_10. The distance between the first electrodes 21_10 and the second electrodes 22_10 may differ from one location to another location on the first electrodes 21_10. For example, a distance DE1 between extended portions RE-E of the first electrodes 21_10 and the second electrodes 22_10 may be smaller than a distance DE2 between connecting portions (RE-C1 and RE-C2) of the first electrodes 21_10 and the second electrodes 22_10 and a distance DE3 between bent portions (RE-B1 and RE-B2) of the first electrodes 21_10 and the second electrodes 22_10. The distance DE2 between the connecting portions (RE-C1 and RE-C2) of the first electrodes 21_10 and the second electrodes 22_10 may be greater than the distance DE3 between the bent portions (RE-B1 and RE-B2) of the first electrodes 21_10 and the second electrodes 22_10. However, the disclosure is not limited to this. The shapes of electrodes (21_10 and 22_10) is the same as the shapes of their respective counterparts of any one of FIGS. 2 through 33, and thus, detailed descriptions thereof will be omitted.

[0218] The arrangement and the shapes of first banks 41_10, a first insulating layer 51_10, and contact electrodes (26_10, 27_10, and 28_10) may vary depending on the arrangement of the first electrodes 21_10 and the second electrodes 22_10.

[0219] The first insulating layer 51_10 may be disposed between, and be in contact with, the

extended portions RE-E of the first electrodes **21_10** and the second electrodes **22_10**. First ends of light-emitting elements **30** may be disposed on the extended portions RE-E of the first electrodes **21_10**, and second ends of the light-emitting elements **30** may be disposed on the second electrodes **22_10**.

[0220] The first banks **40** may include first sub-banks **41_10** and a second sub-bank **42_10**. The first sub-banks **41_10** and the second sub-bank **42_10** may extend in a second direction DR2, and the first sub-banks **41_10** may have a different width in a first direction DR1 than the second sub-bank **42_10**. As the first sub-banks **41_10** have a larger width in the first direction DR1 than the second sub-bank **42_10**, the first sub-banks **41_10** may be disposed across the boundaries between the first subpixel PX1 and neighboring subpixels PXn, in the first direction DR1, of the first subpixel PX1. For example, the first sub-banks **41_10** may be disposed not only in an emission area EMA of the first subpixel PX1, but also between the emission area EMA of the first subpixel PX1 and emission areas EMA of the neighboring subpixels PXn. Accordingly, portions of a second bank **45_10** that extend in the second direction DR2 may be disposed on the first sub-banks **41_10**. Two first sub-banks **41_10** may be disposed in portion in each subpixel PXn, and one second sub-bank **42_10** may be disposed between the two first sub-banks **41_10**.

[0221] The second sub-bank **42_10** may extend in the second direction DR2 in the middle of the emission area EMA of the first subpixel PX1. The second sub-bank **42_10** may have a smaller width than the first sub-banks **41_10** and may be spaced apart from the first sub-banks **41_10**.

[0222] The extended portions RE-E of the first electrodes **21_10** and the second bank **45_10** may be disposed on the first sub-banks **41_10**. Extended portions RE-E of first electrodes **21_10** of the neighboring subpixels PXn may be disposed on the first sub-banks **41_10**. For example, extended portions RE-E of two first electrodes **21_10** may be disposed on one first sub-bank **41_10**, and two second electrodes **22_10** may be disposed on one second sub-bank **42_10**. The second electrodes **22_10** may be disposed along both sides of the second sub-bank **42_10** that extend in the second direction DR2 and may be spaced apart from each other with the second sub-bank **42_10** therebetween.

[0223] One of the first electrodes **21_10** may include a contact portion RE-P, in which a first contact hole CT1 is formed, and the other first electrode **21_10** may not include a contact portion RE-P. Similarly, one of the second electrodes **22_10** may include a contact portion RE-P, in which a second contact hole CT2 is formed, and the other second electrode **22_10** may not include a contact portion RE-P. Some of the electrodes (**21_10** and **22_10**) electrically connected to a first transistor TR1 or a second voltage line VL2 may receive electrical signals via contact holes (CT1 and CT2), and the other electrodes (**21_10** and **22_10**) may receive electrical signals via the contact electrodes (**26_10**, **27_10**, and **28_10**).

[0224] Both ends of each of the light-emitting elements **30** are disposed on the extended portions RE-E of the first electrodes **21_10** and the second electrodes **22_10**, on the first insulating layer **51_10**. First ends of the light-emitting elements **30** where second semiconductor layers **32** are disposed may be disposed on the first electrodes **21_10**. Accordingly, first ends of first-type light-emitting elements **30-1**, which are disposed between leftward electrodes (**21_10** and **22_10**) that are disposed on the left side of the center of the first subpixel PX1, and first ends of second-type light-emitting elements **30-2**, which are disposed between rightward electrodes (**21_10** and **22_10**) that are disposed on the right side of the center of the first subpixel PX1, may face opposite directions.

[0225] The display device **10** may include a relatively large number of electrodes (**21_10** and **22_10**) and may thus include a relatively large number of contact electrodes (**26_10**, **27_10**, and **28_10**).

[0226] The contact electrodes (**26_10**, **27_10**, and **28_10**) may include a first contact electrode **26_10**, which is disposed on one of the first electrodes **21_10**, a second contact electrode **27_10**, which is disposed on one of the second electrodes **22_10**, and a third contact electrode **28_10**, which is disposed on the other first electrode **21_10** and the other second electrode **22_10** and

surrounds the second contact electrode **27_10**.

[0227] The first contact electrode **26_10** may be disposed on one of the first electrodes **21_10**. For example, the first contact electrode **26_10** may be disposed on the extended portion RE-E of the first electrode **21_10** where the first ends of the first-type light-emitting elements **30-1** are disposed. The first contact electrode **26_10** may be in electrical contact with the first ends of the first-type light-emitting elements **30-1** and with the extended portion RE-E of the first electrode **21_10** where the first ends of the first-type light-emitting elements **30-1** are disposed. The second contact electrode **27_10** may be disposed on one of the second electrodes **22_10**. For example, the second contact electrode **27_10** may be disposed on the second electrode **22_10** where the first ends of the second-type light-emitting elements **30-2** are disposed. The second contact electrode **27_10** may be in electrical contact with the first ends of the second-type light-emitting elements **30-2** and with the second electrode **22_10** where the first ends of the second-type light-emitting elements **30-2** are disposed. The first and second contact electrodes **26_10** and **27_10** may be in electrical contact with the electrodes (**21_10** and **22_10**) where the first and second contact holes CT1 and CT2 are formed. The first contact electrode **26_10** may be in electrical contact with the first electrode **21_10** electrically connected to the first transistor TR1, via the first contact hole CT1, and the second contact electrode **27_10** may be in electrical contact with the second electrode **22_10** electrically connected to the second voltage line VL2, via the second contact hole CT2. The first and second contact electrodes **26_10** and **27_10** may transmit electrical signals applied thereto from the first transistor TR1 or the second voltage line VL2 to the light-emitting elements **30**. The first and second contact electrodes **26_10** and **27_10** may be substantially the same as their respective counterparts of any one of FIGS. 2 through 33.

[0228] Electrodes (**21_10** and **22_10**) where the contact holes (CT1 and CT2) are not formed may be further disposed in the first subpixel PX1. The electrodes (**21_10** and **22_10**) where the contact holes (CT1 and CT2) are not formed may be in a floating state with substantially no electrical signals applied directly thereto from the first transistor TR1 or the second voltage line VL2. The third contact electrode **28_10** may be disposed on the electrodes (**21_10** and **22_10**) where the contact holes (CT1 and CT2) are not formed, and electrical signals transmitted to the light-emitting elements **30** may flow via the third contact electrode **28_10**.

[0229] The third contact electrode **28_10** may be disposed on the electrodes (**21_10** and **22_10**) where the contact holes (CT1 and CT2) are not formed and may be disposed to surround the second contact electrode **27_10**. The third contact electrode **28_10** may include portions that extend in the second direction DR2 and a portion that extends in the first direction DR1 to connect the portions that extend in the second direction DR2, and may thus surround the second contact electrode **27_10**. The portions of the third contact electrode **28_10** that extend in the second direction DR2 may be disposed on the electrodes (**21_10** and **22_10**) where the contact holes (CT1 and CT2) are not formed, to be in electrical contact with the light-emitting elements **30**. For example, portion of the third contact electrode **28_10** that is disposed on the second electrode **22_10** where the second contact hole CT2 is not formed may be in electrical contact with second ends of first light-emitting elements **30A**, and portion of the third contact electrode **28_10** that is disposed on the first electrode **21_10** where the first contact hole CT1 is not formed may be in electrical contact with first ends of second light-emitting elements **30B**. The portion of the third contact electrode **28_10** that extends in the first direction DR1 may overlap, but may not be directly connected to, the second electrode **22_10** where the second contact hole CT2 is formed, because of the presence of an insulating layer (not illustrated) therebetween.

[0230] Electrical signals transmitted from the first contact electrode **26_10** to the first ends of the first-type light-emitting elements **30-1** may be delivered to the third contact electrode **28_10**, which is in electrical contact with second ends of the first-type light-emitting elements **30-1**. The third contact electrode **28_10** may transmit these electrical signals to the first ends of the second light-emitting elements **30B** so that the signals may be transmitted to the second electrodes **22_10** via the

second contact electrode **27_10**. Accordingly, electrical signals for the light-emitting elements **30** to emit light can be transmitted only to one of the first electrodes **21_10** and the second electrode **22_10**, and the first-type light-emitting elements **30-1** and the second-type light-emitting elements **30-2** can be electrically connected in series via the third contact electrode **28_10**.

[0231] In concluding the detailed description, those skilled in the art will appreciate that many variations and modifications can be made to the embodiments without substantially departing from the principles of the disclosure. Therefore, the disclosed embodiments of the disclosure are used in a generic and descriptive sense only and not for purposes of limitation.

Claims

1. A display device comprising: a planarization layer disposed on the substrate; a plurality of first banks disposed on the planarization layer and spaced apart from one another; a first electrode and a second electrode disposed on different first banks of the plurality of first banks and spaced apart from each other; a first insulating layer disposed on the planarization layer and partially overlapping the first and second electrodes; first light-emitting elements disposed on the first insulating layer so that a first end and a second end of each of the first light-emitting elements are disposed on the first electrode and the second electrode, respectively; and second light-emitting elements disposed on the first insulating layer so that a first end and a second end of each of the second light-emitting elements are disposed on the first electrode and the second electrode, respectively, wherein a distance between the first light-emitting elements and the substrate is smaller than a distance between the second light-emitting elements and the substrate the planarization layer includes recesses between the plurality of first banks where a top surface of the planarization layer is recessed, at least portions of the first and second electrodes are disposed in the recesses, and the first light-emitting elements are disposed in the recesses.
 2. The display device of claim 1, wherein the planarization layer includes portions between the plurality of first banks where the recesses are not formed, and the second light-emitting elements are disposed on the portions of the planarization layer where the recesses are not formed.
 3. The display device of claim 1, further comprising: a transistor disposed between the substrate and the planarization layer; and a data conductive layer disposed between the transistor and the planarization layer and including a first voltage line and a second voltage line, wherein the first electrode is electrically connected to the first voltage line via the transistor, and the second electrode is electrically connected to the second voltage line.
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